

Update on LAPPD R&D at IJS

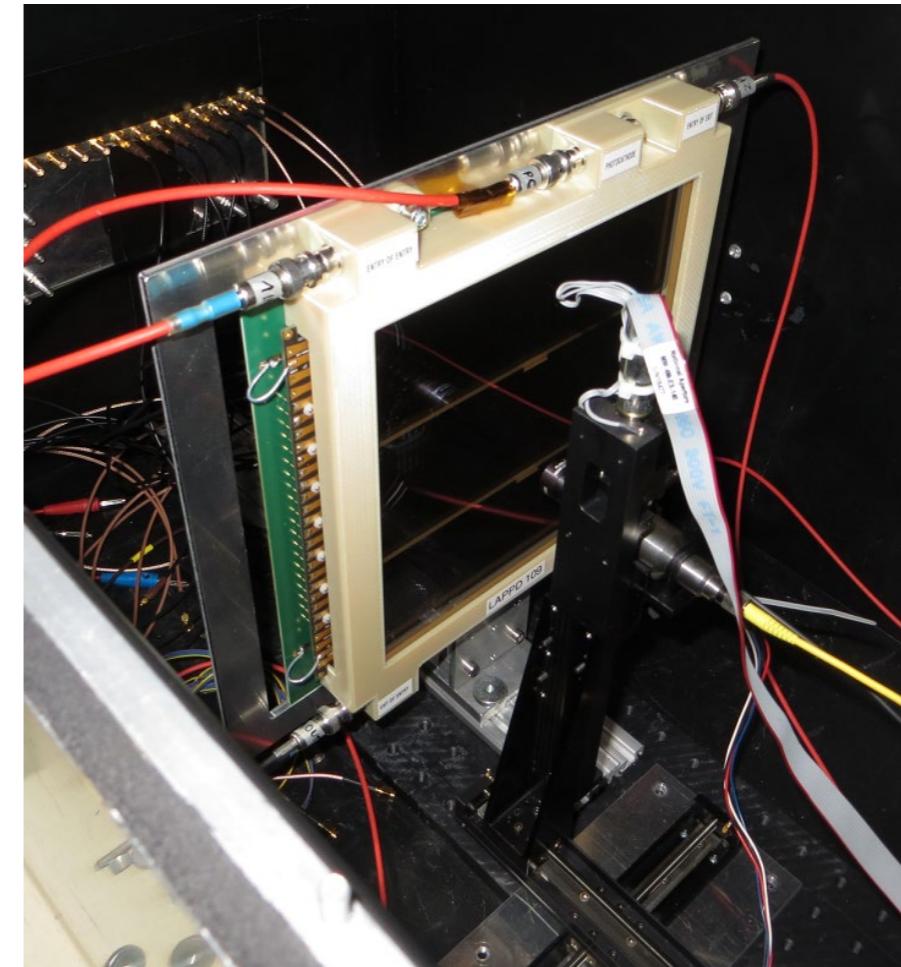
Samo Korpar et al.

University of Maribor and Jožef Stefan Institute, Ljubljana
LAPPD Workshop, 20 April 2023

Outline:

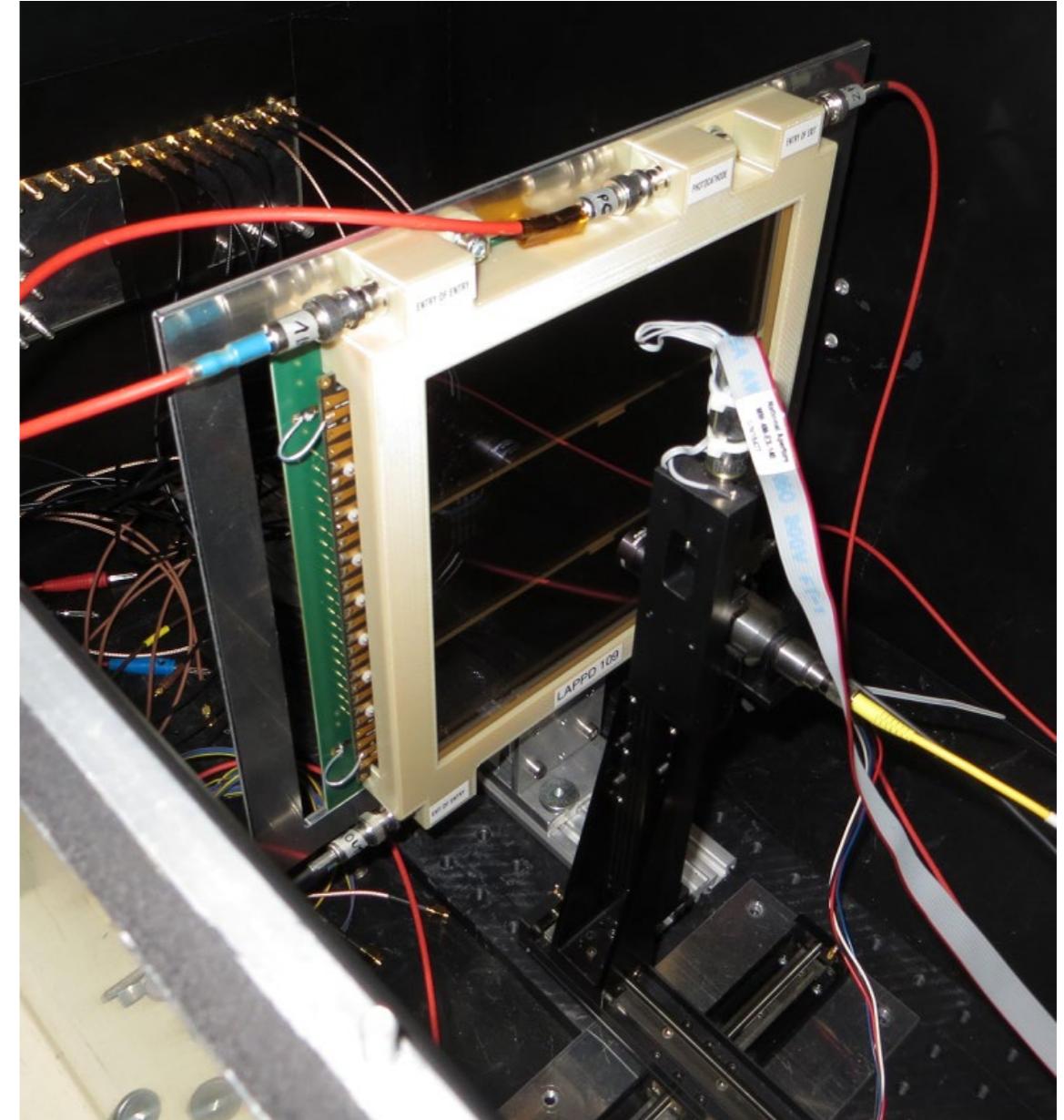
- LAPPD, test setup
- Timing and charge sharing
 - timing variation
- Spacer dead space
- FastIC update

F9-IJS
Preliminary!

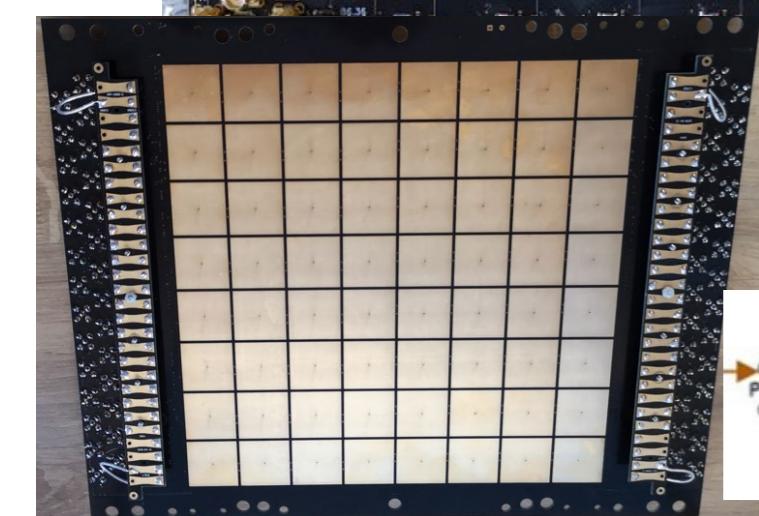
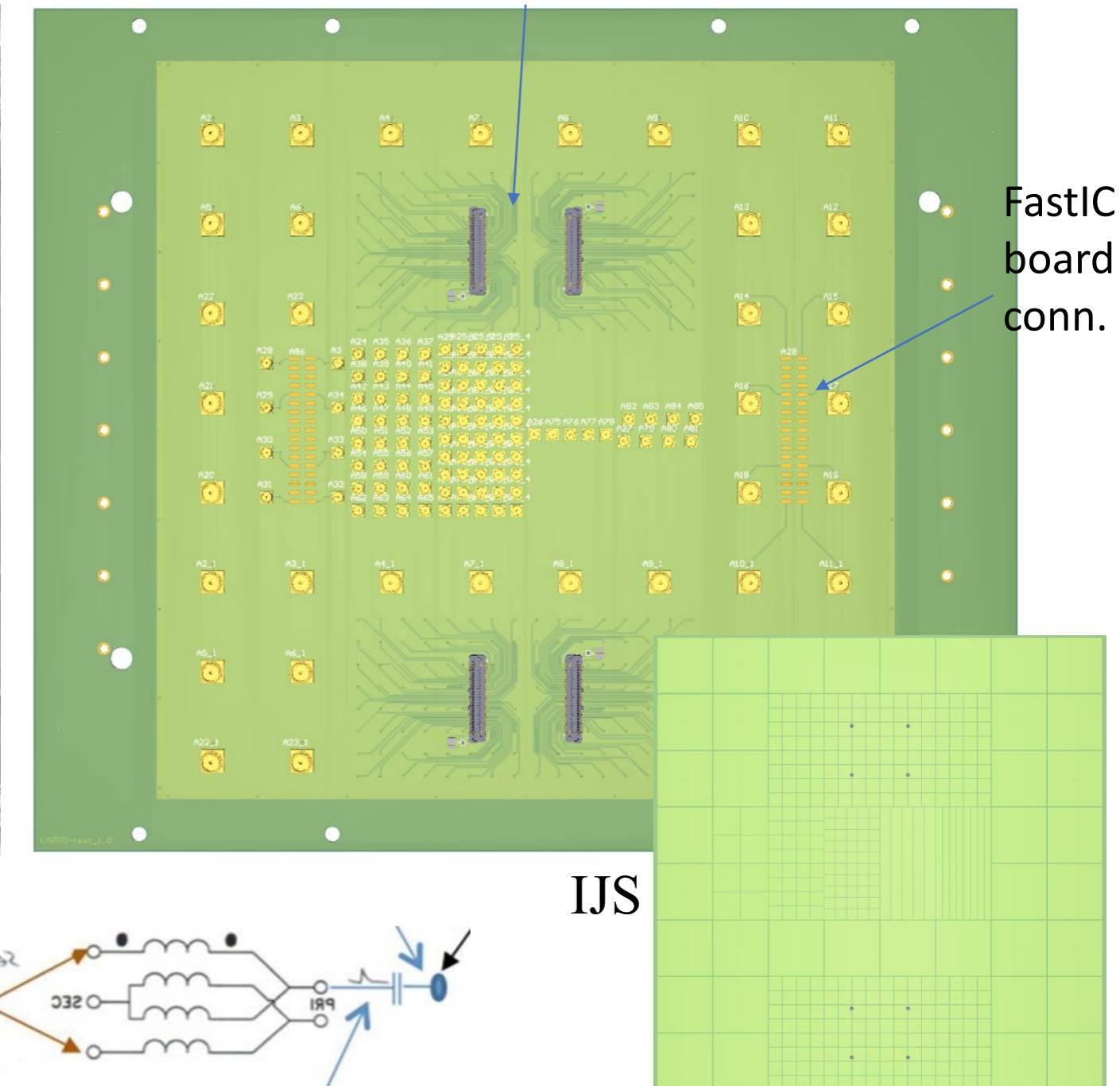
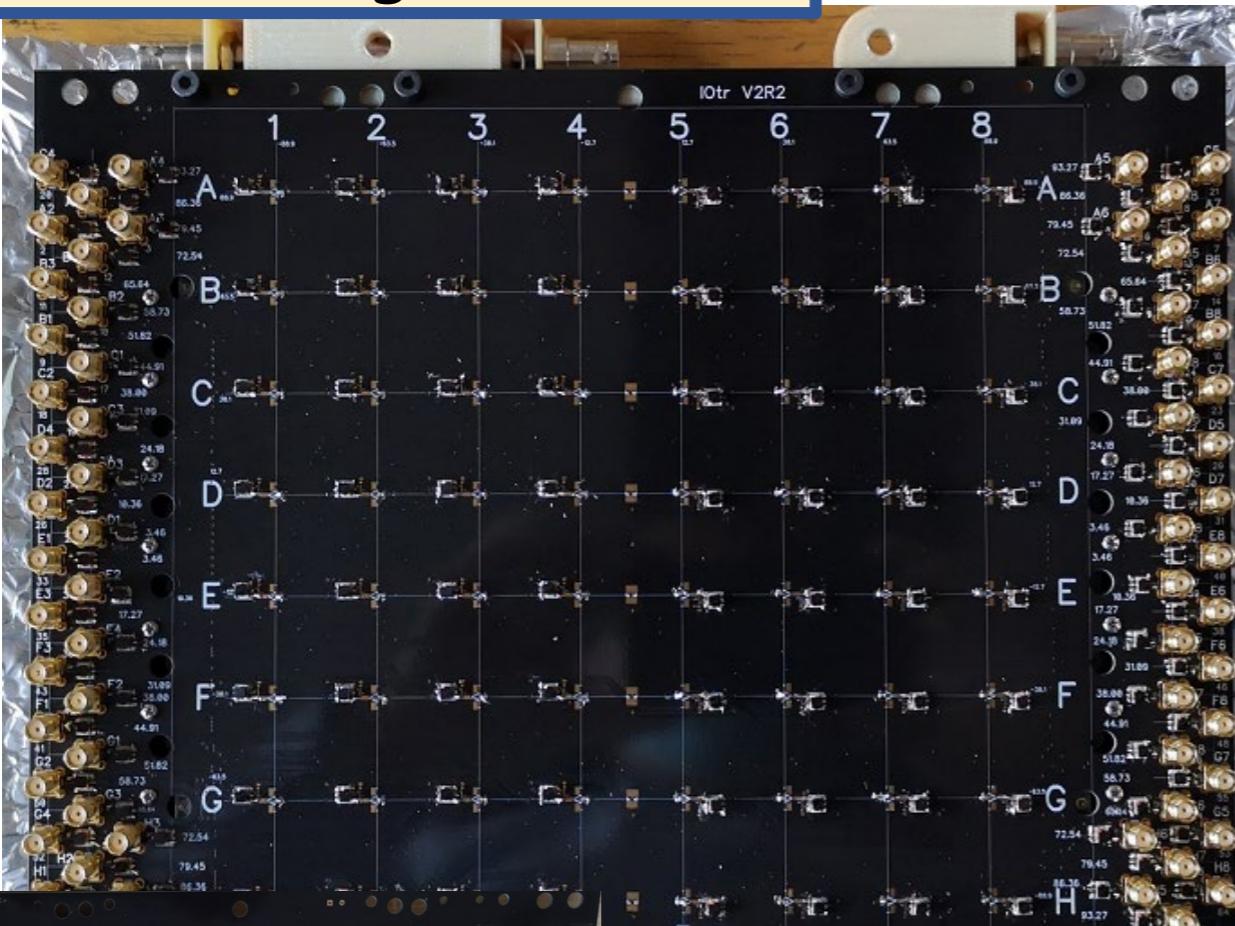


LAPPD #109:

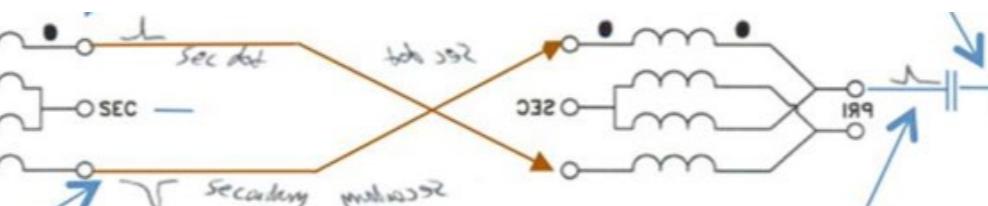
- $\approx 200 \times 200 \text{ mm}^2$
- $20 \mu\text{m}$ pores @ $25 \mu\text{m}$ pitch
- resistive anode plane, capacitive coupled readout
- 5 mm thick glass backplate
- 5 HV levels: PC, MCP1in, MCP1out, MCP2in, MCP2out
and resistive anode at ground potential
- Standard setup with QDC, TDC, 3D stage ...
- TDC value corrected for time-walk
- ALPHALAS PICOPOWER™-LD Series of Picosecond Diode Lasers – 405 nm
- FWHM $\approx 20 \text{ ps}$
- light spot diameter $< 100 \mu\text{m}$
- Preliminary results.



LAPPD - sensing electrodes

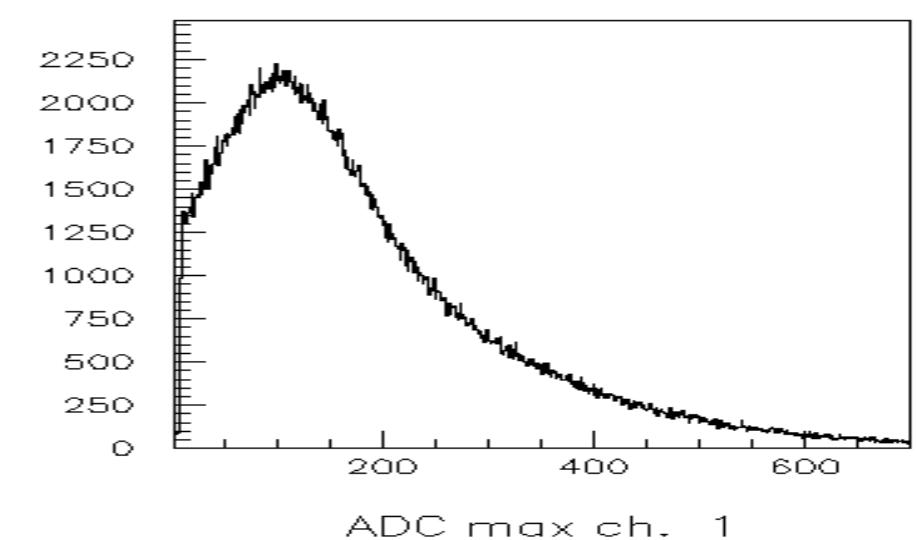
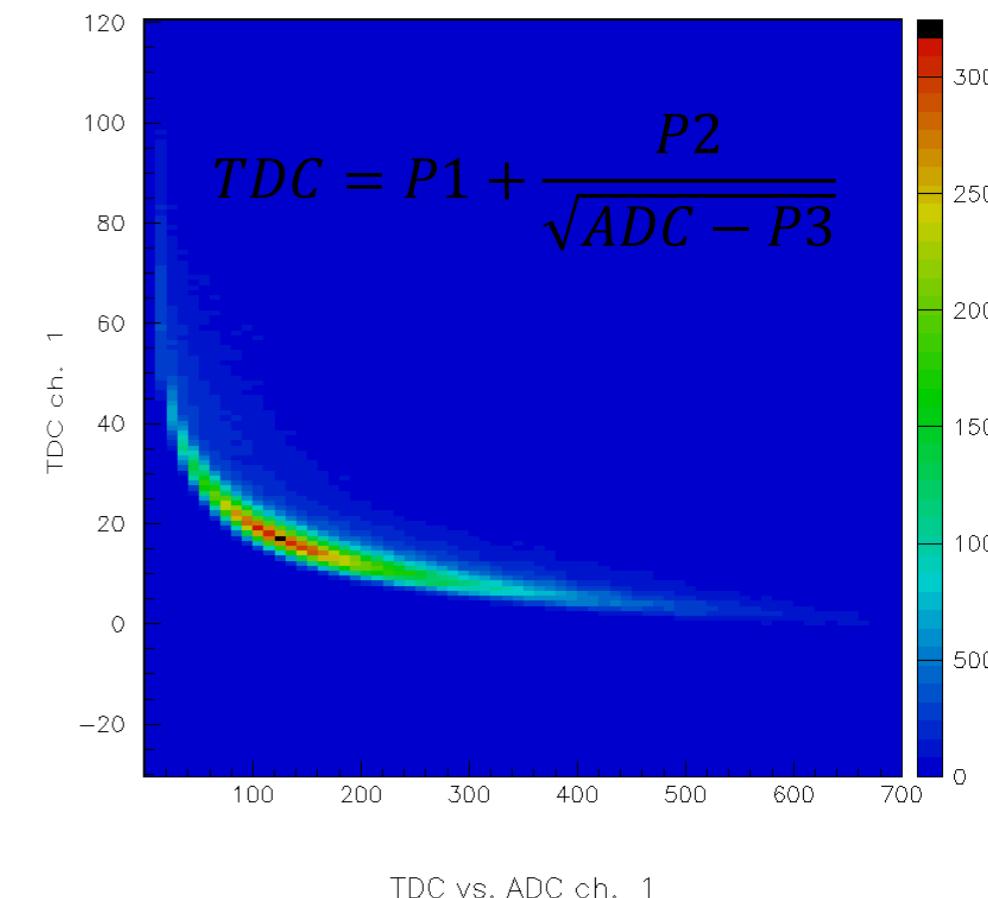
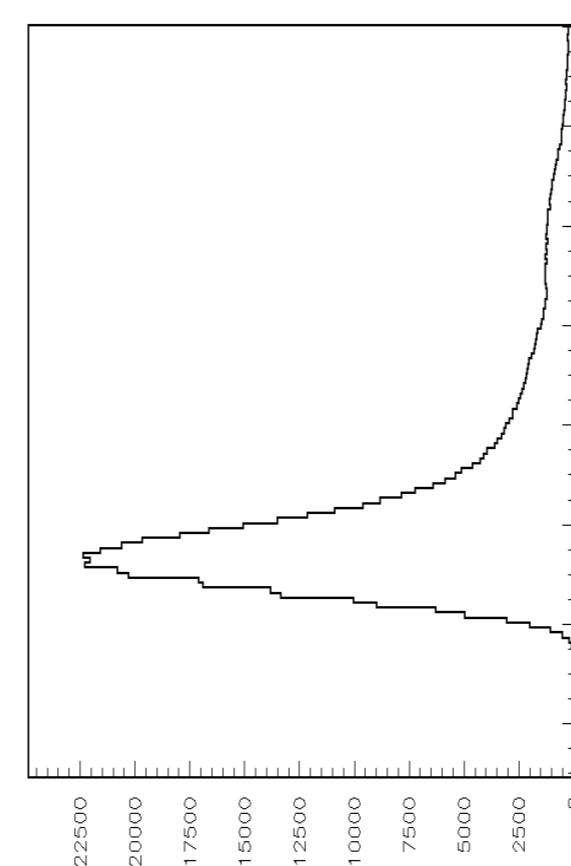
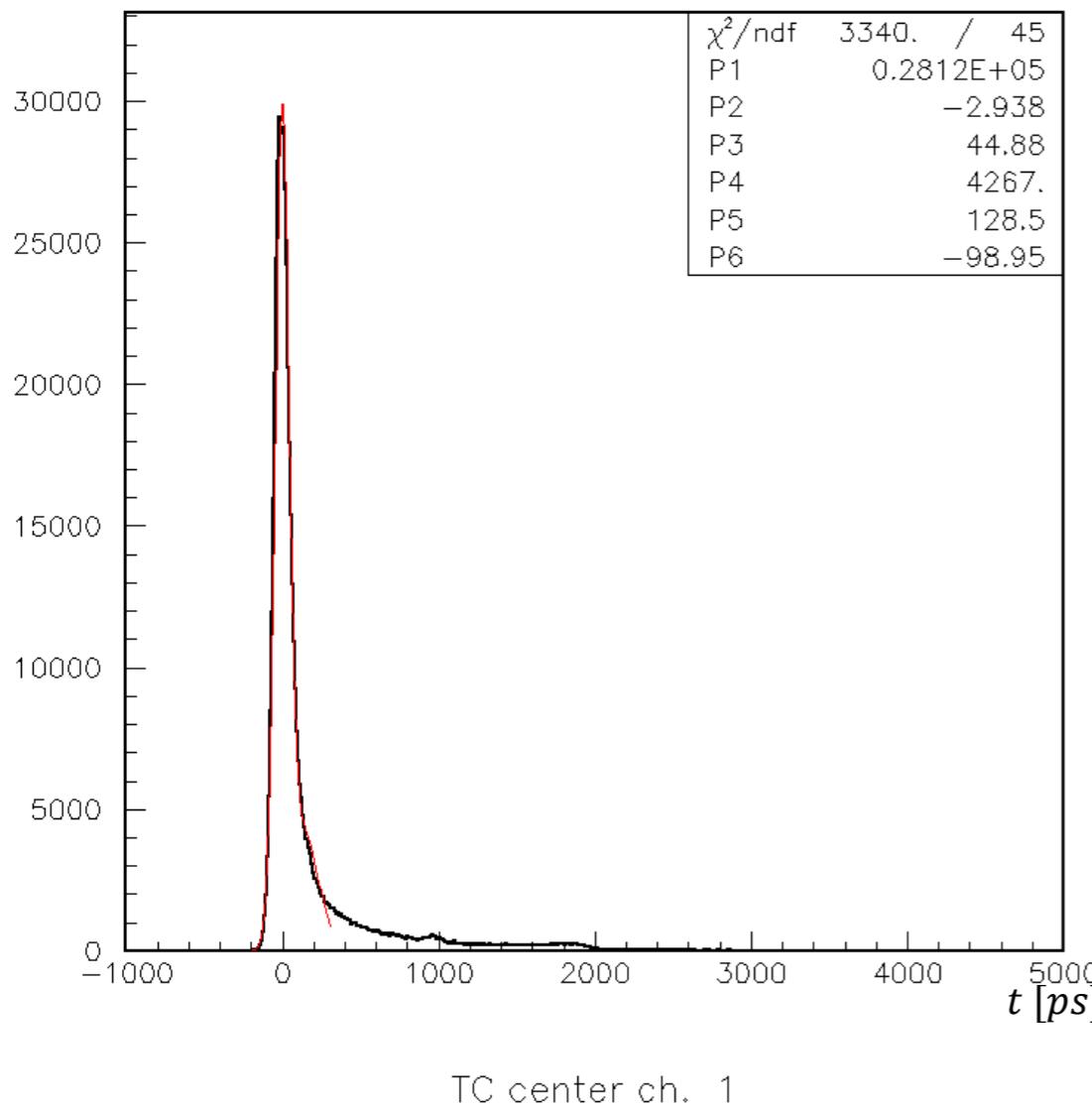


INCOM



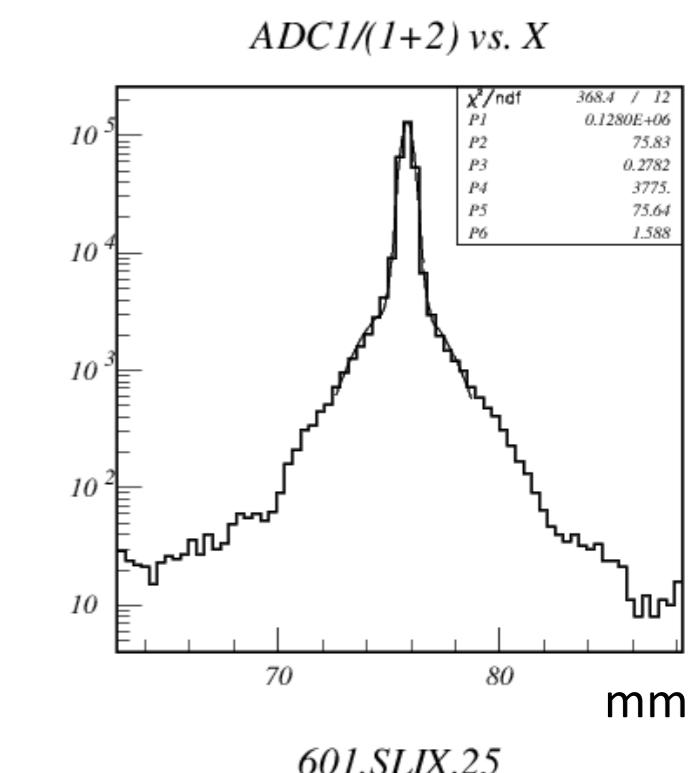
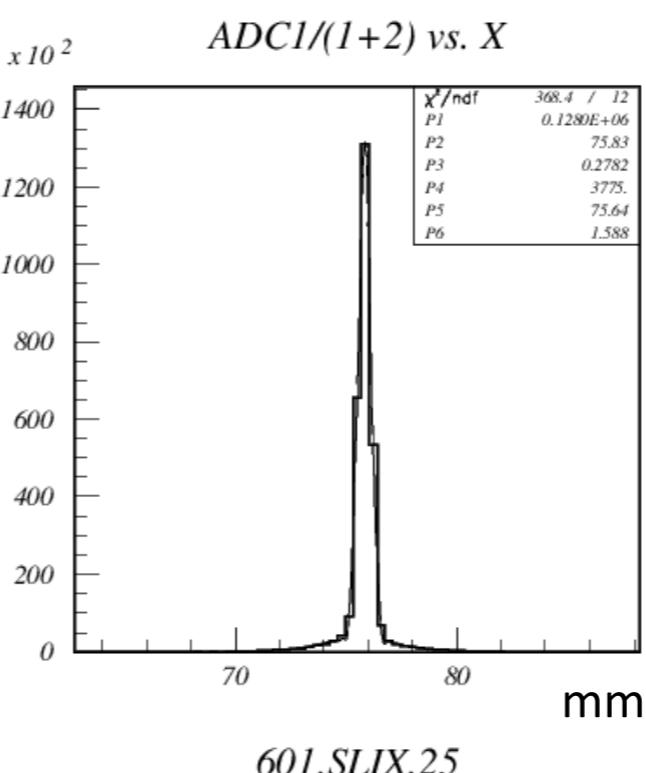
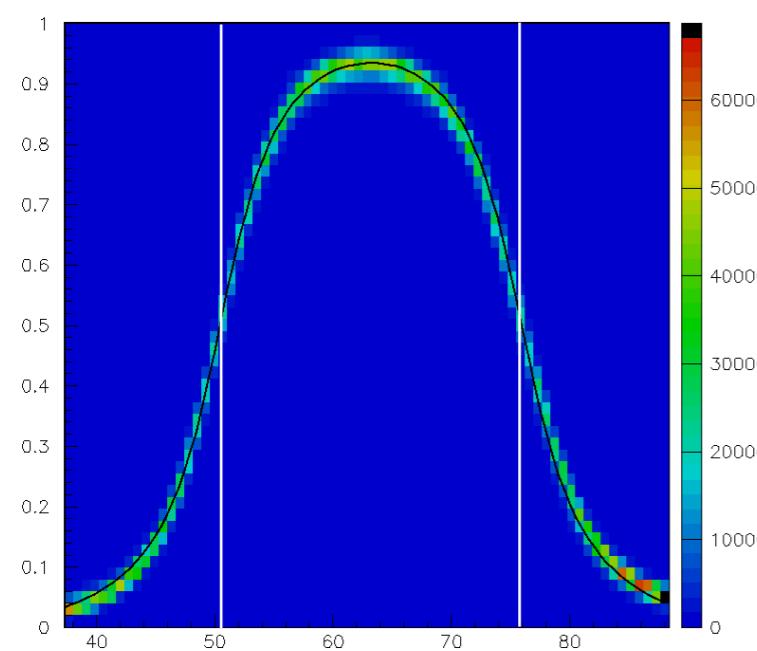
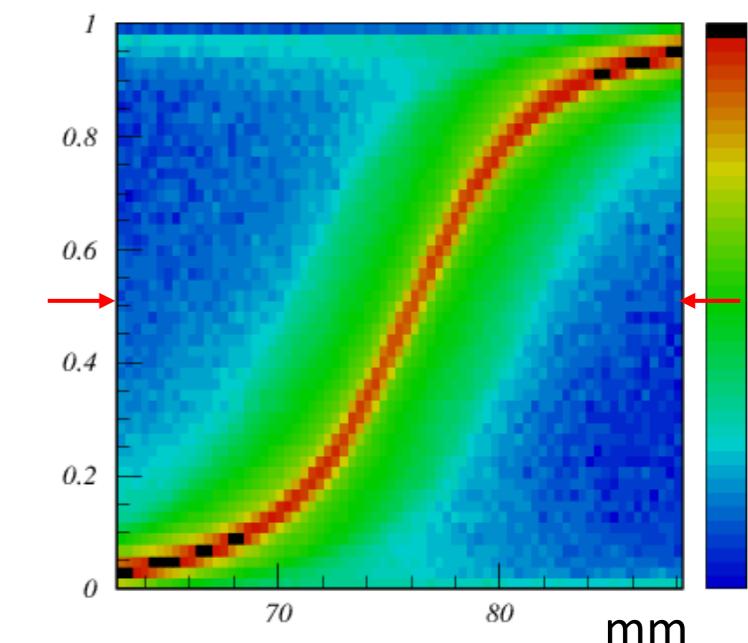
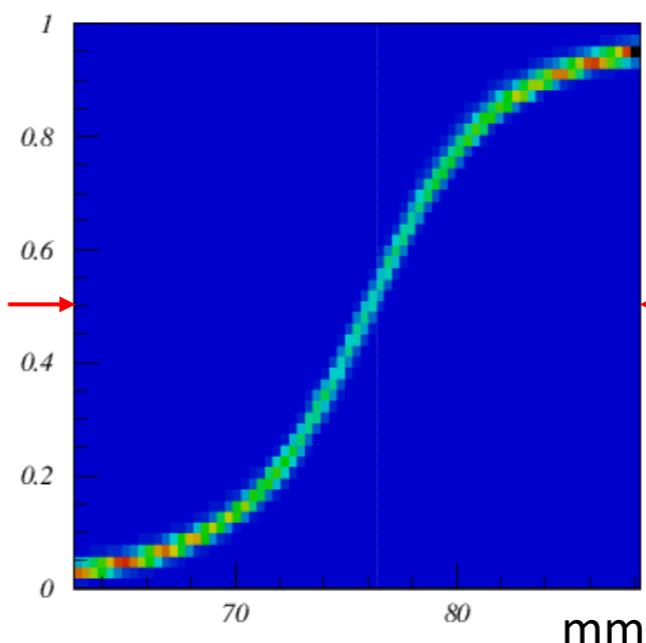
LAPPD - time-walk correction

- TDC corrected for time-walk
- timing resolution (prompt peak) $\sigma \approx 40$ ps after time-walk correction



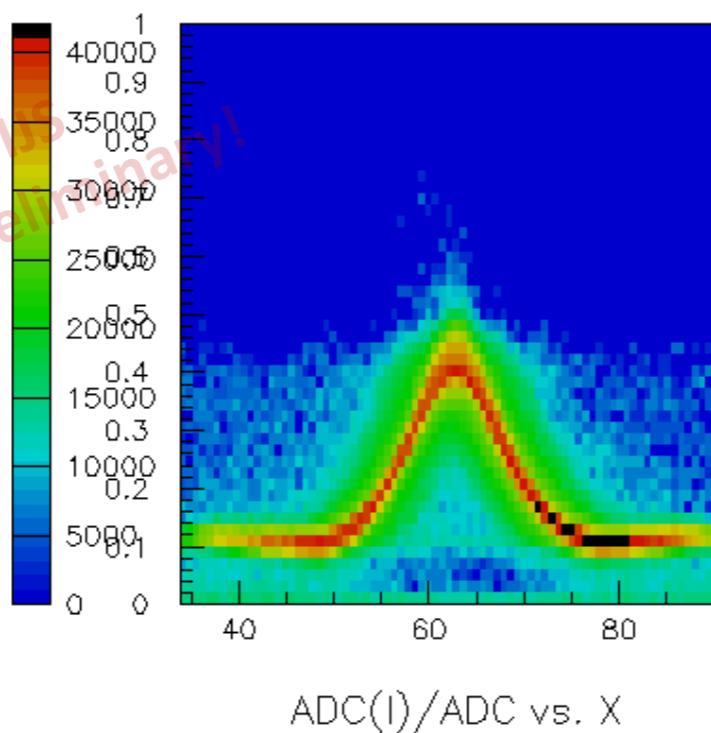
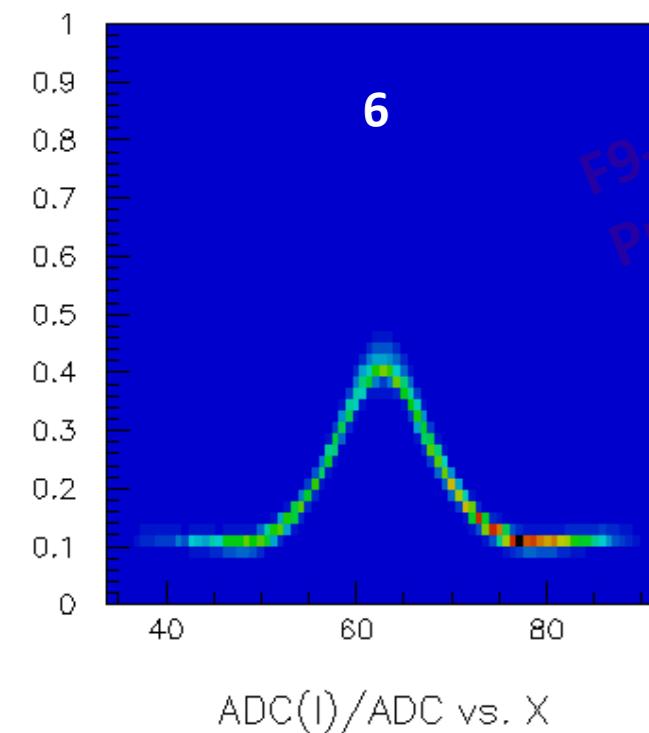
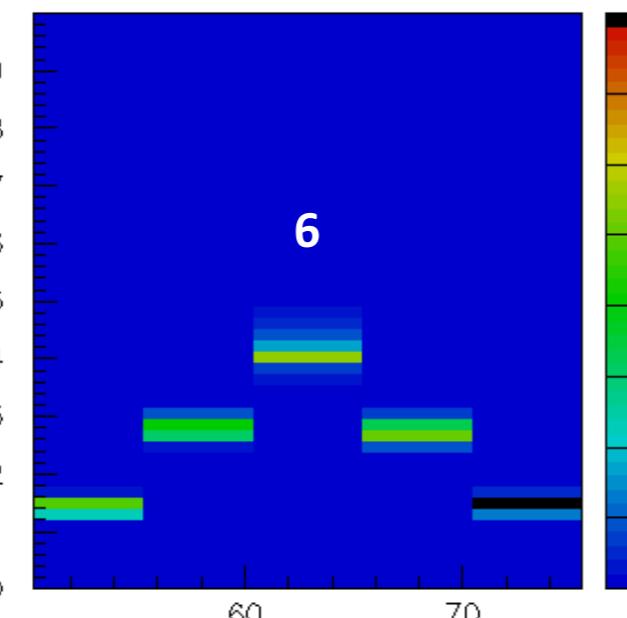
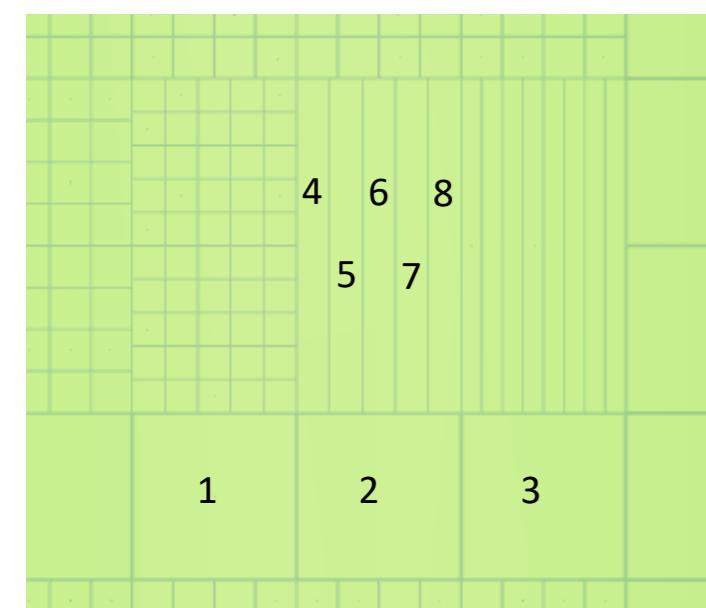
LAPPD - charge sharing

- more detailed scan between the centres of adjacent pads (top)
- central slice where signal is equally split between the pads (bottom)
- narrow peak is due to the light spot size and photoelectron spread
- longer tail from photoelectron backscattering - ≈ 6 mm on each side
- ≈ 3 mm PC – MCP1 distance

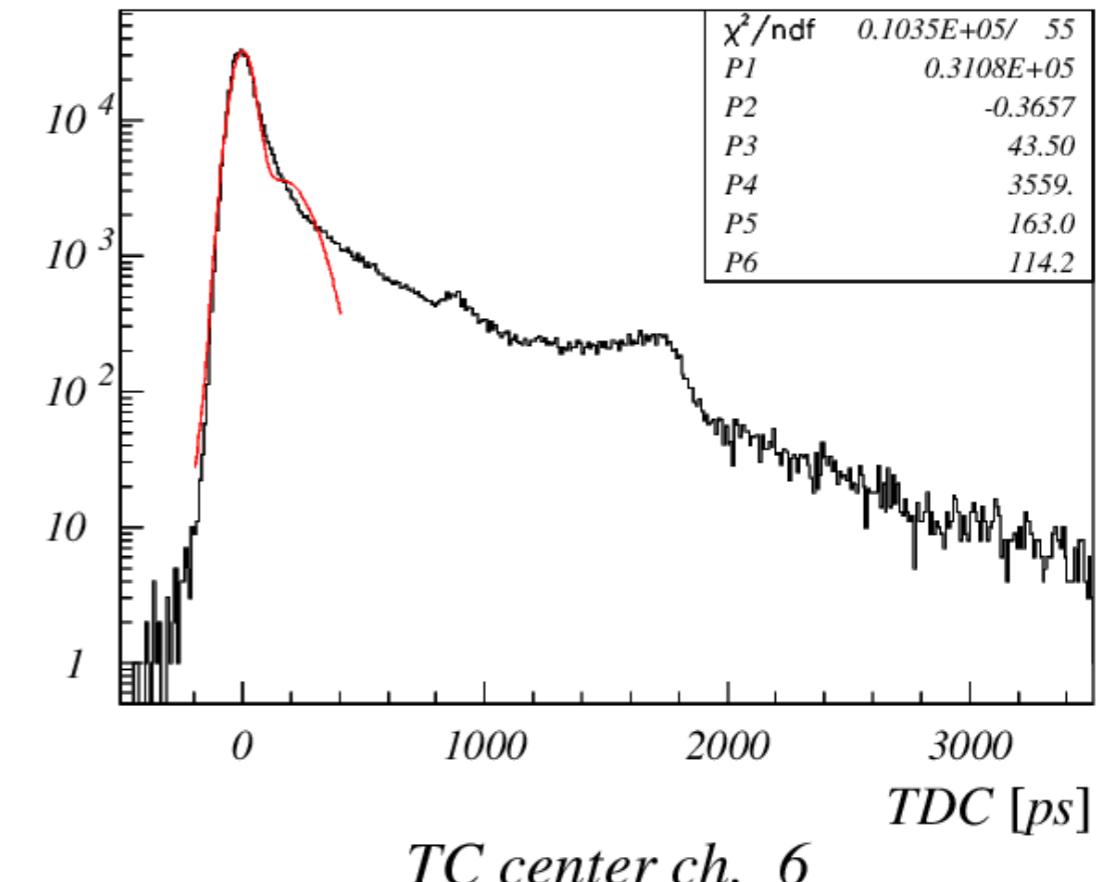


LAPPD - 5mm strips

- charge sharing for 5 mm strips

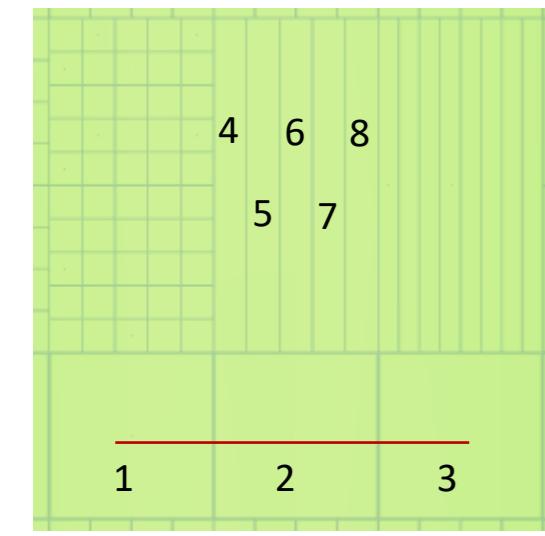


counts

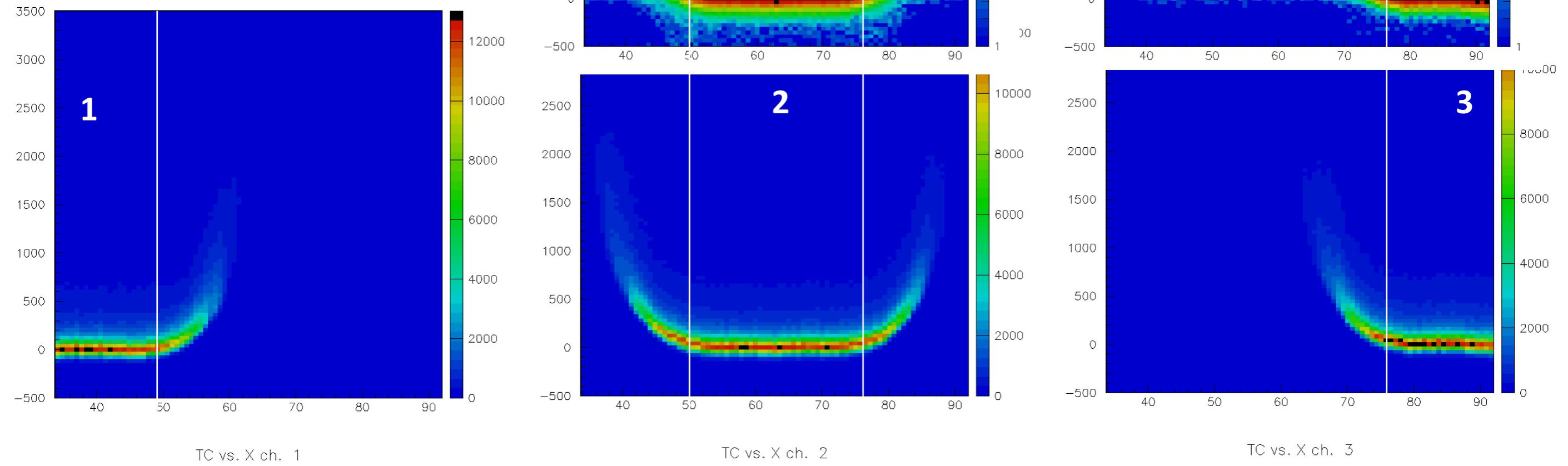


TC center ch. 6

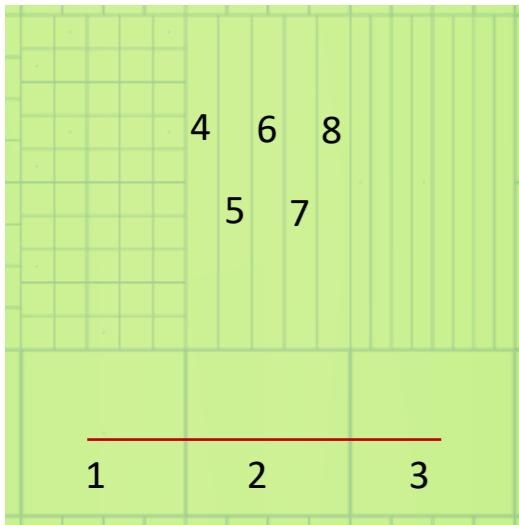
Timing variation



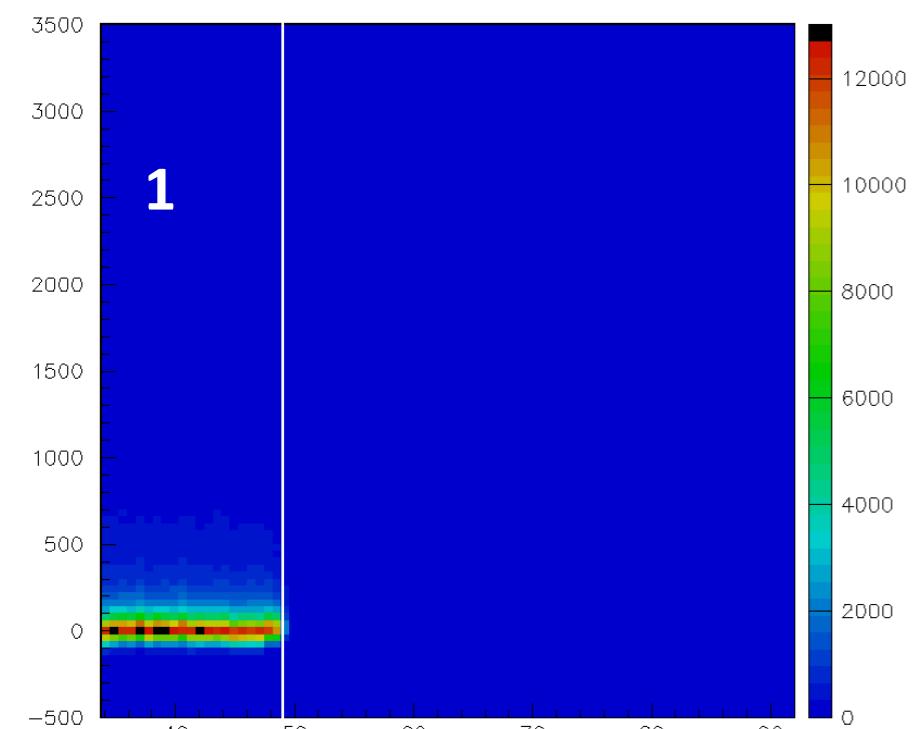
- all signals detected by channel



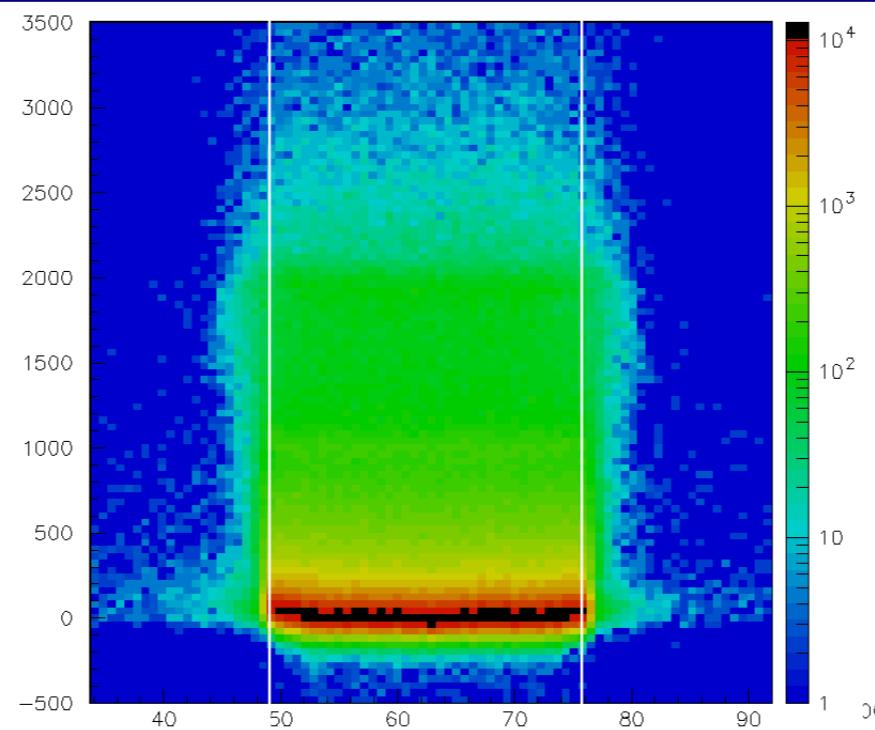
Timing variation



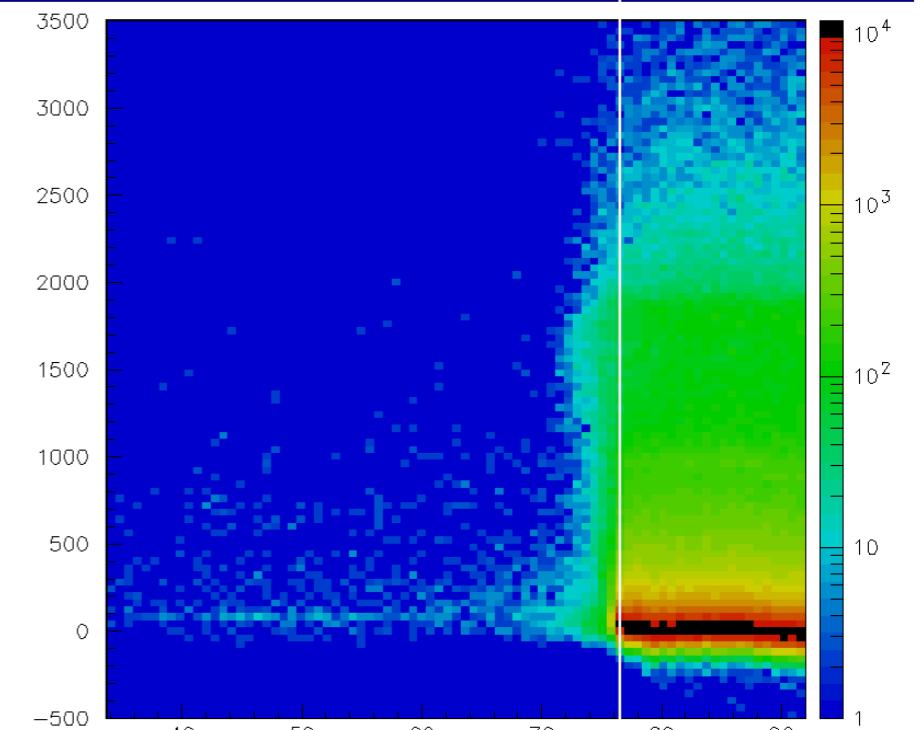
- max. signal detected by channel



TC vs. X max ch. 1



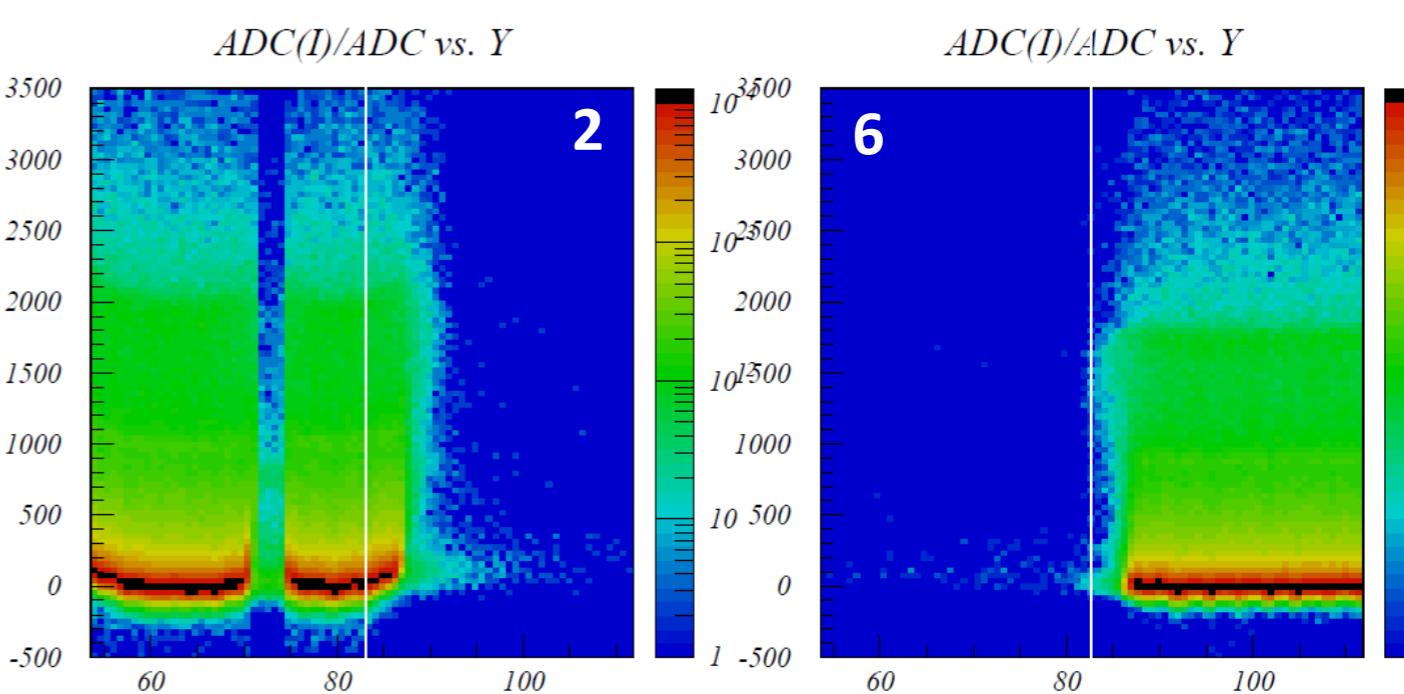
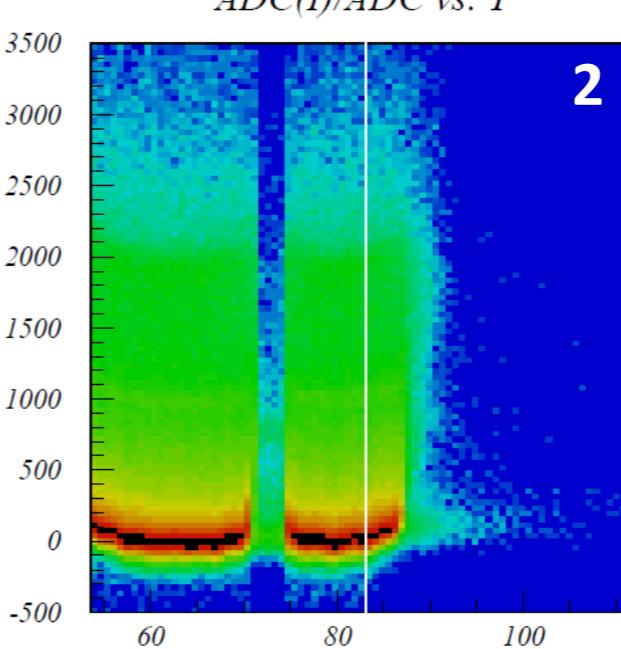
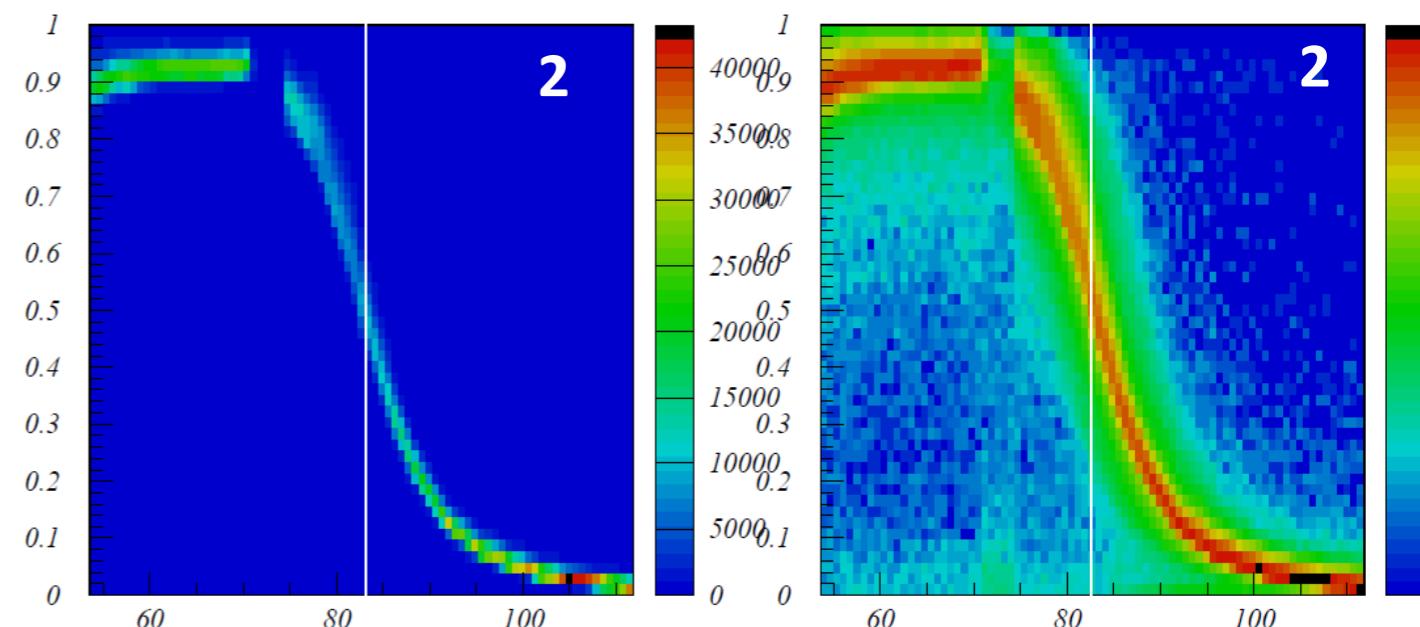
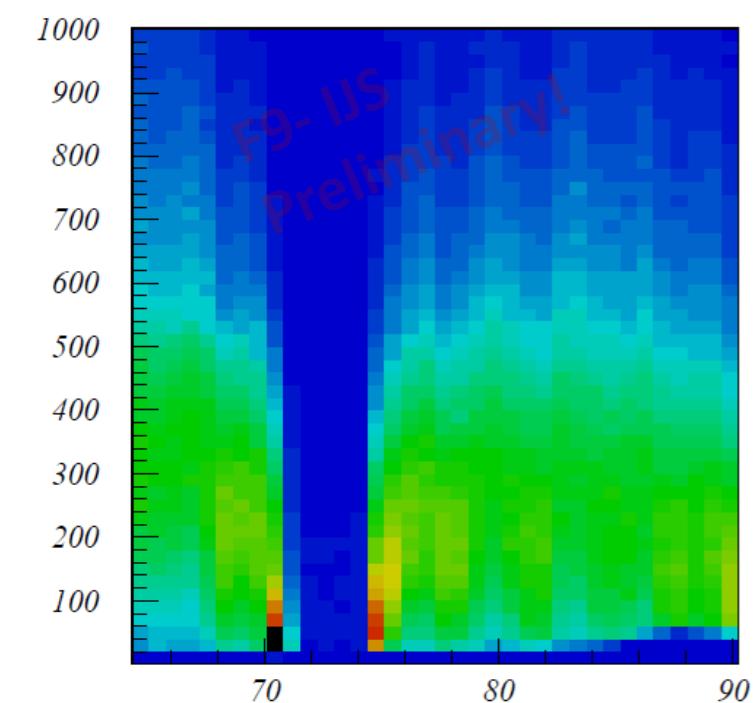
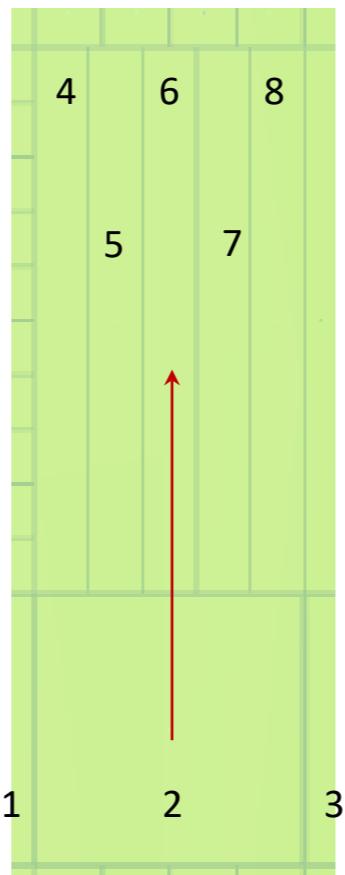
TC vs. X max ch. 2



TC vs. X max ch. 3

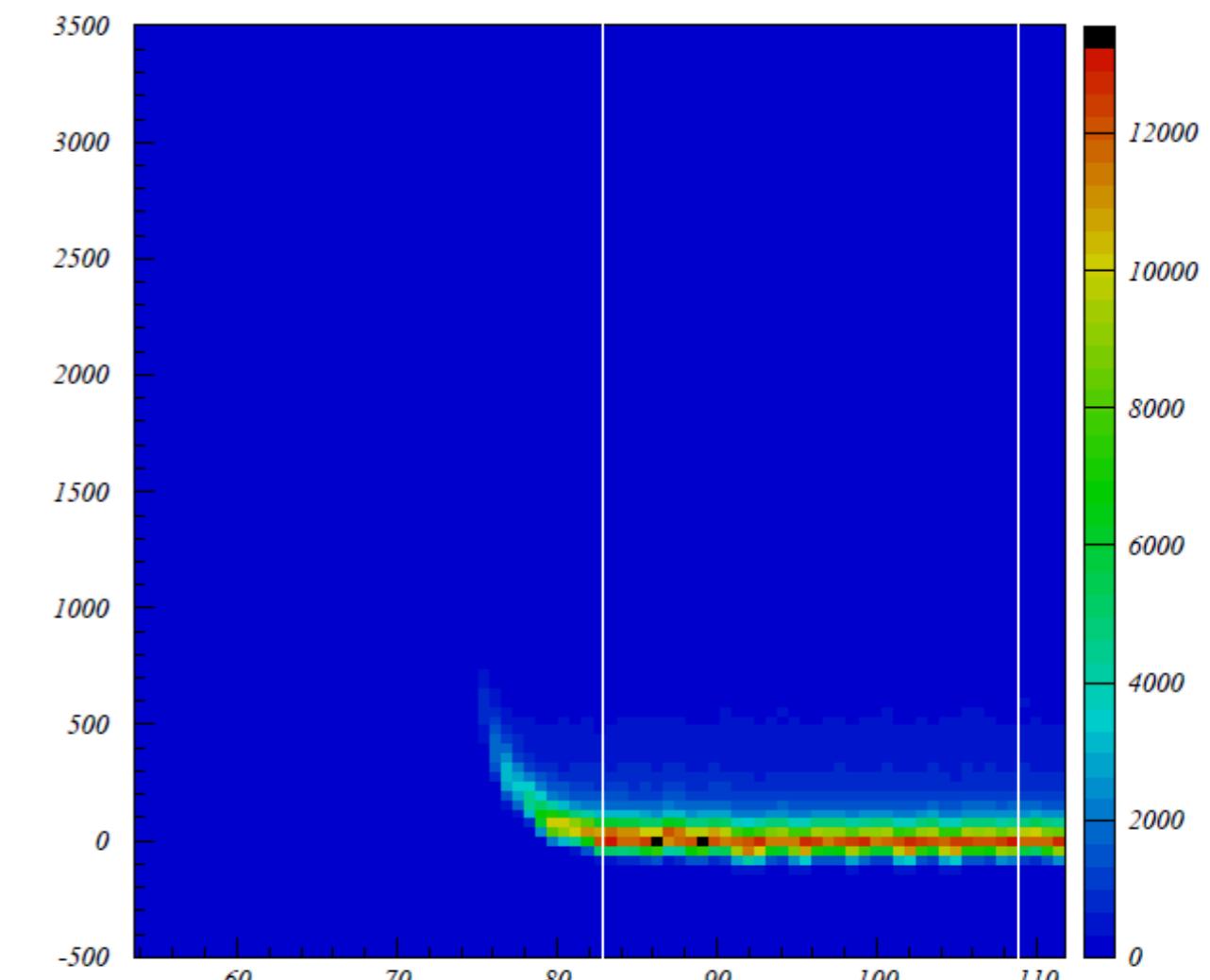
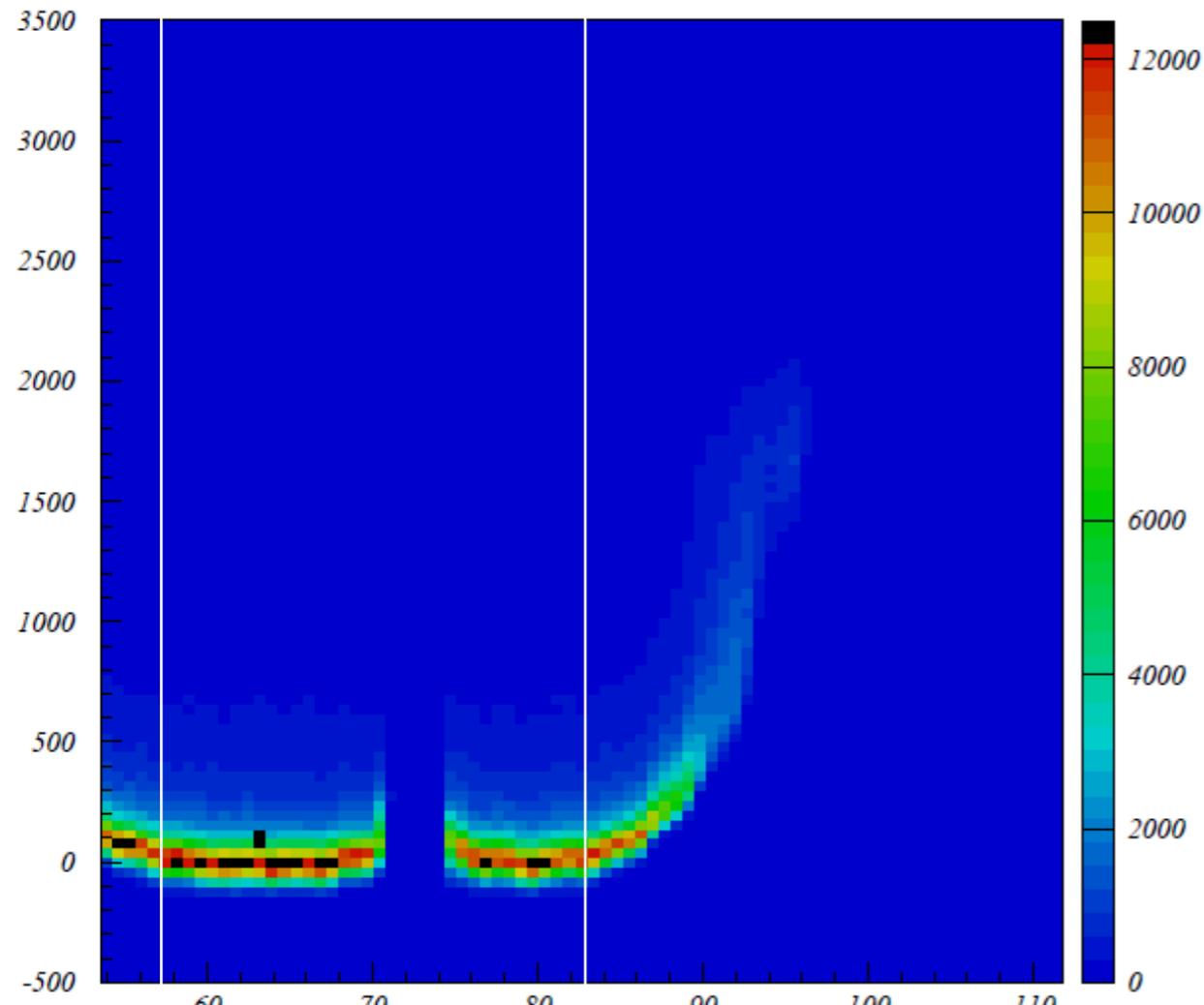
Spacer bar area

- scan across spacer bar in y direction
- gain drops within $\approx 10 \text{ mm}$ area, dead area $\approx 4 \text{ mm}$



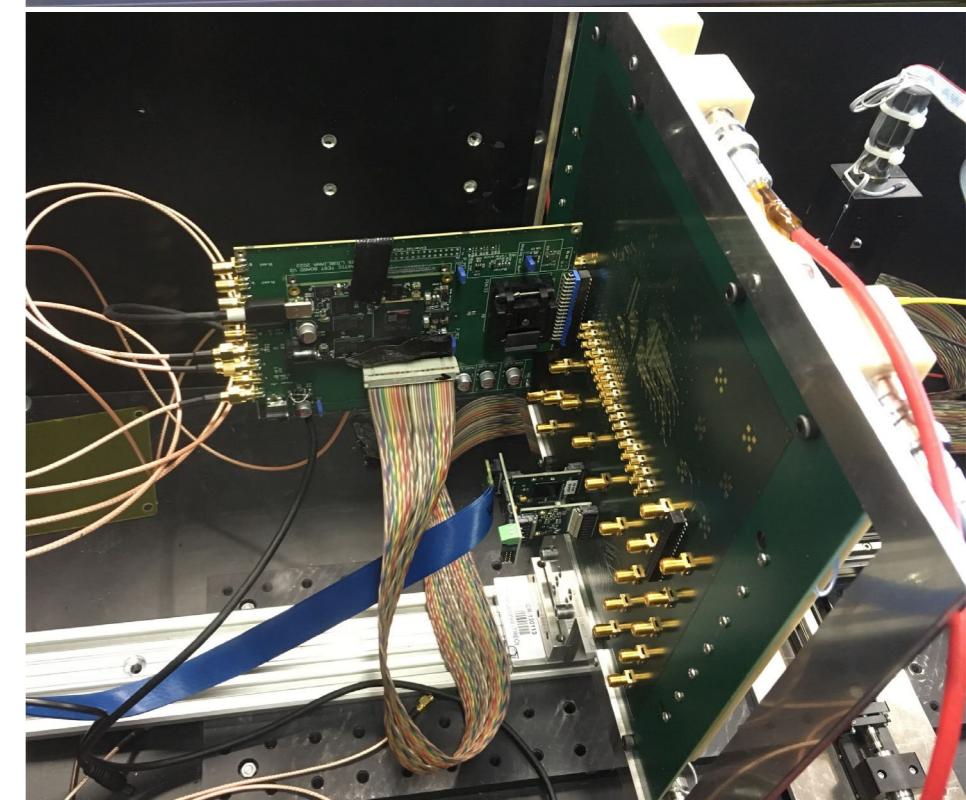
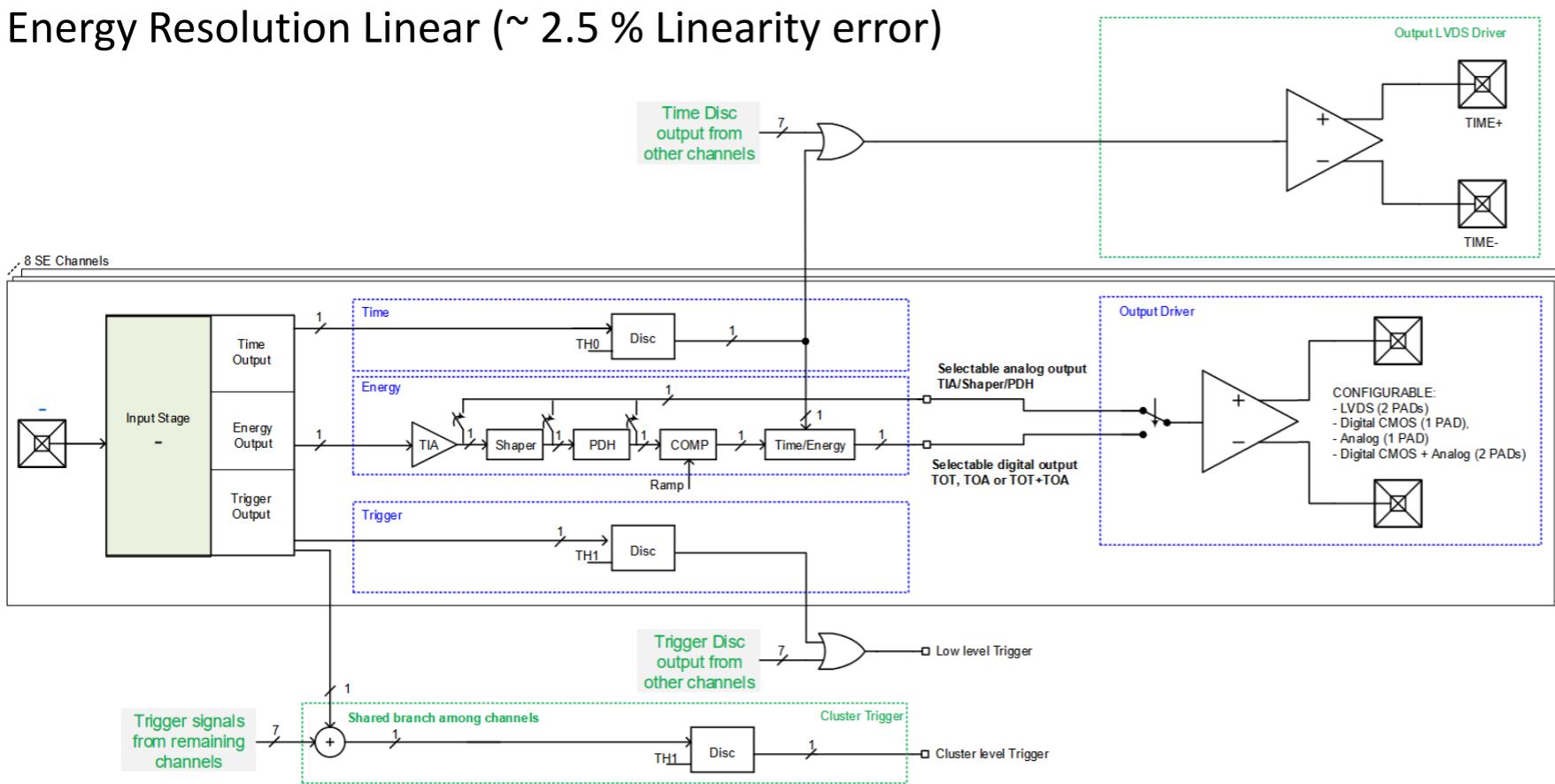
Spacer bar area

- scan across spacer bar in y direction

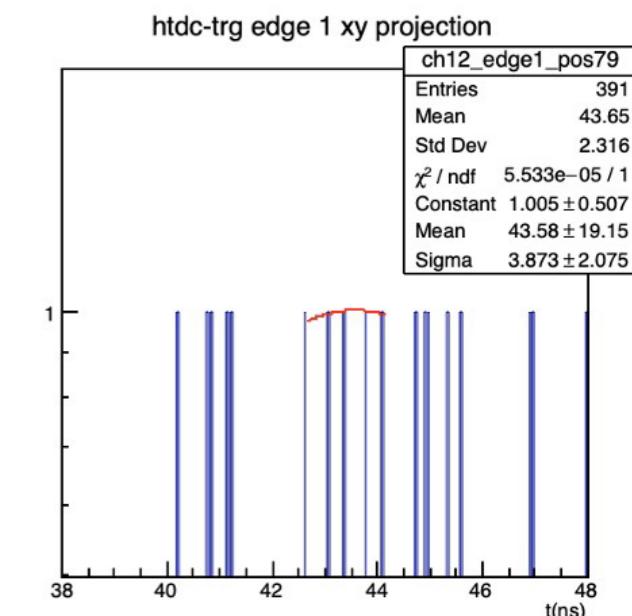
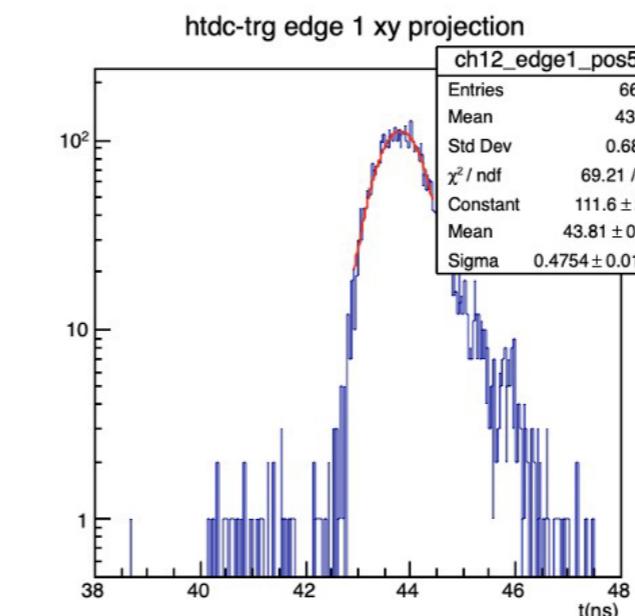
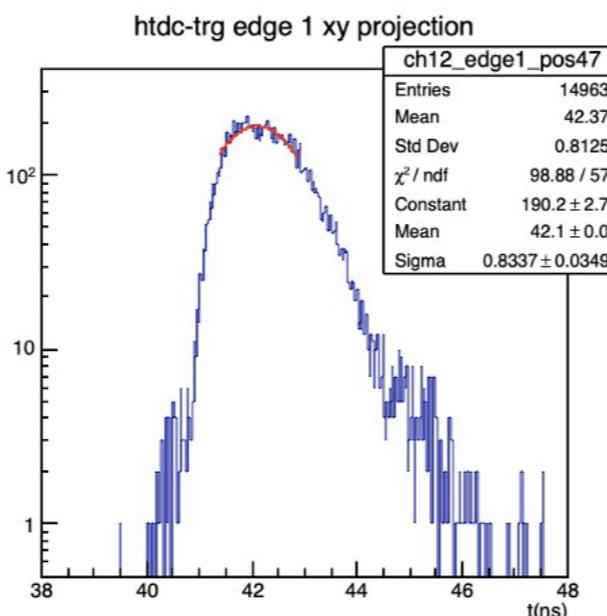
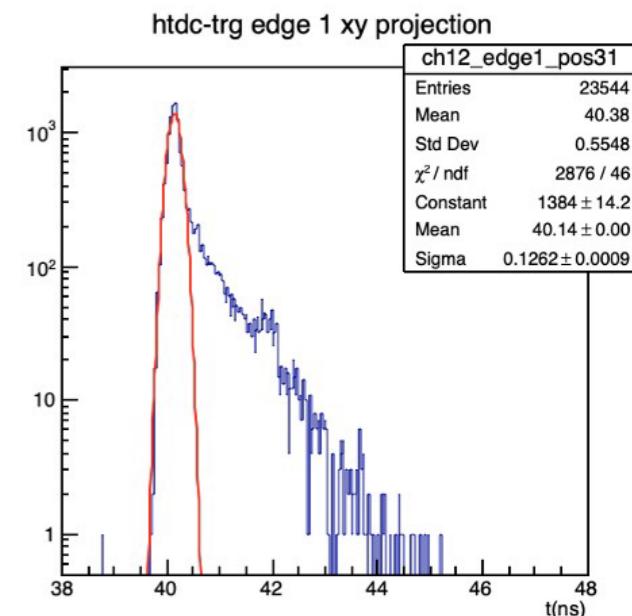
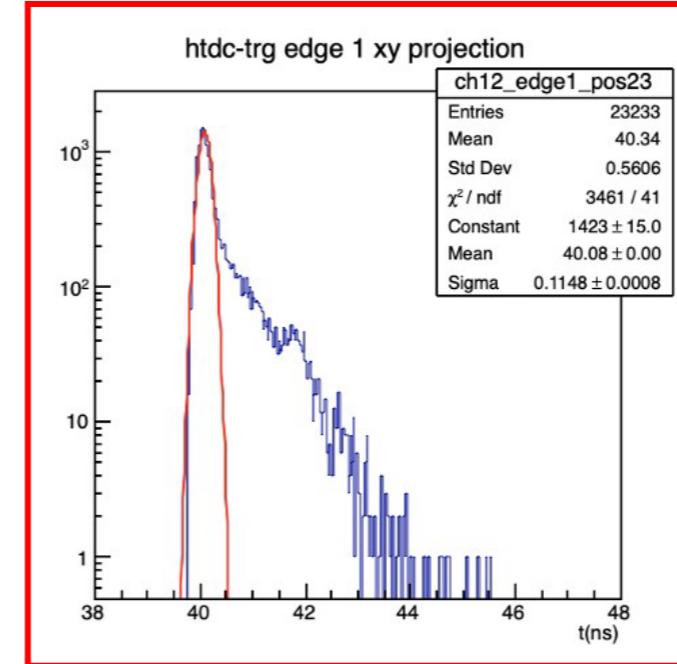
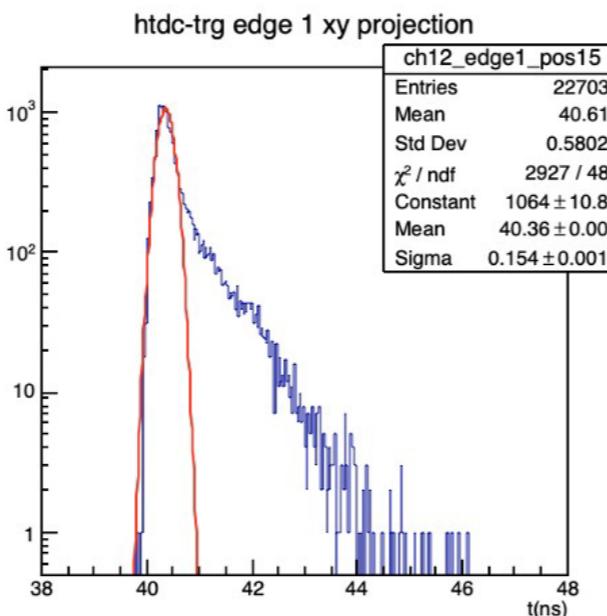
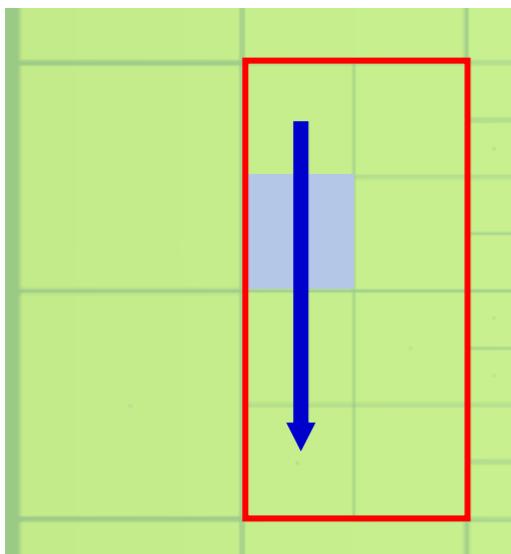


LAPPD + FastIC

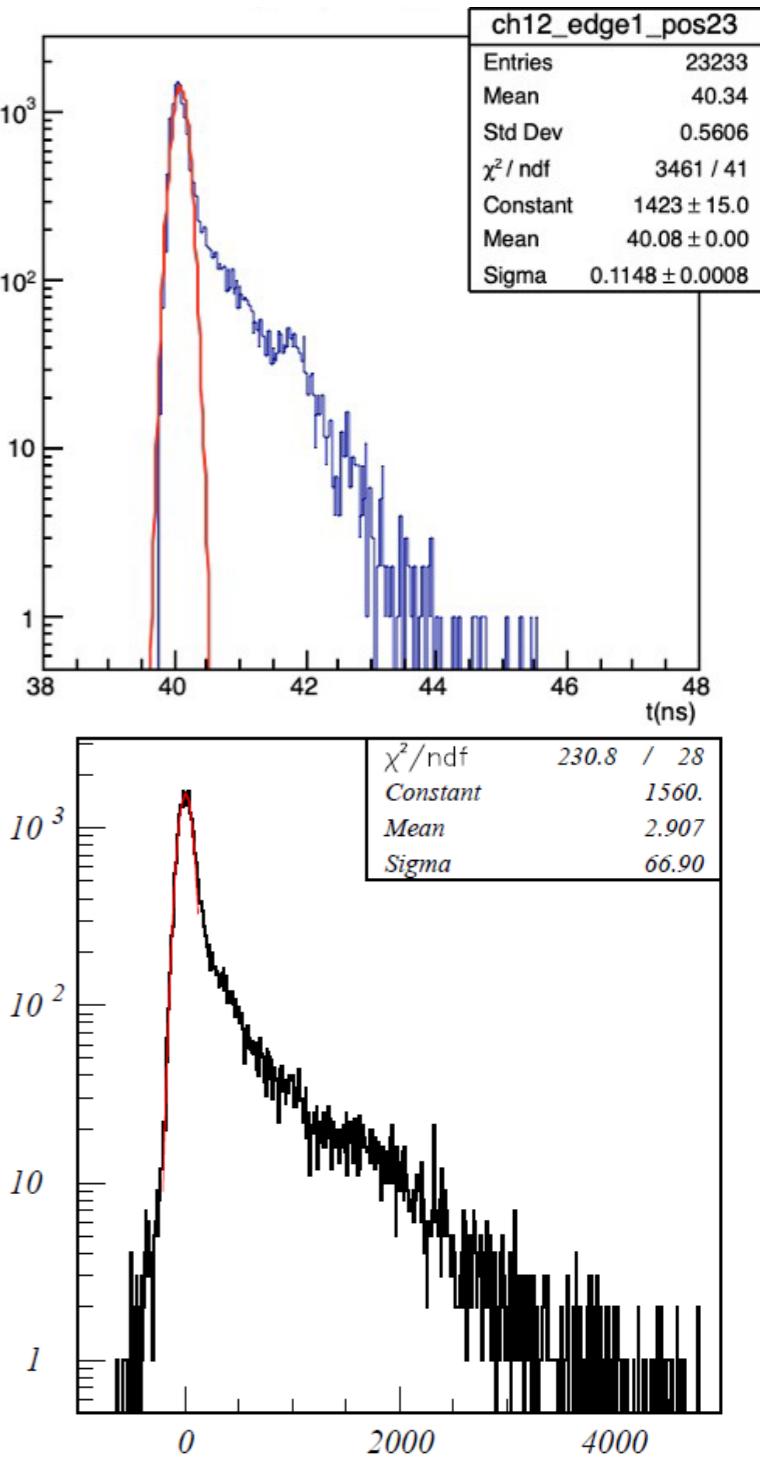
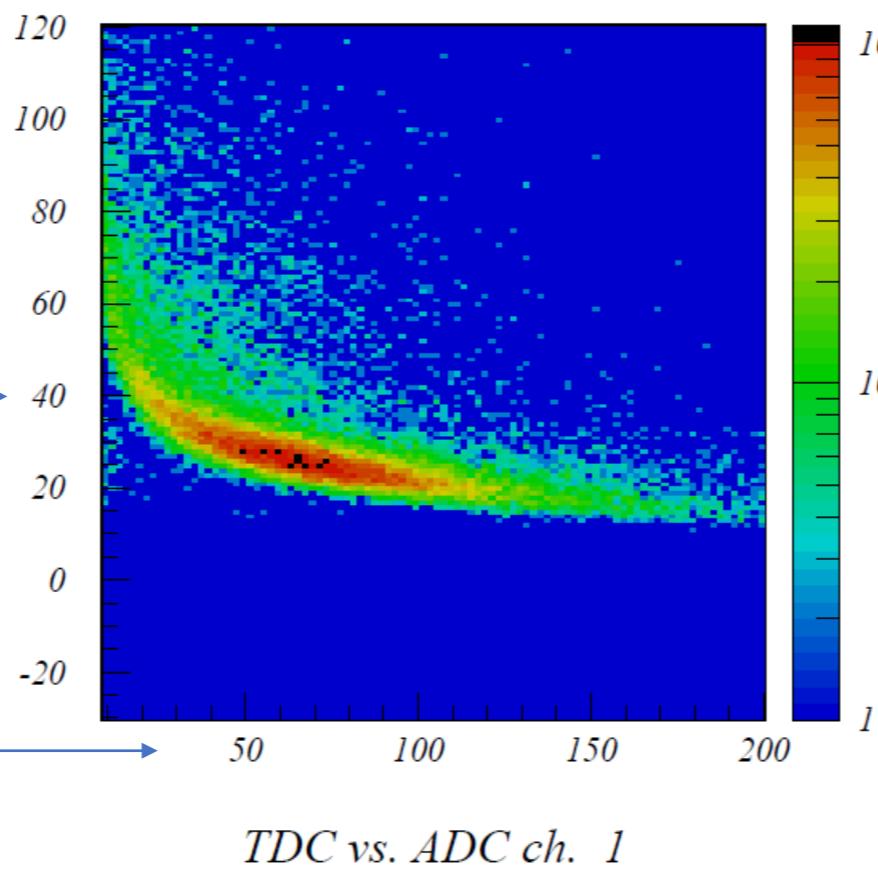
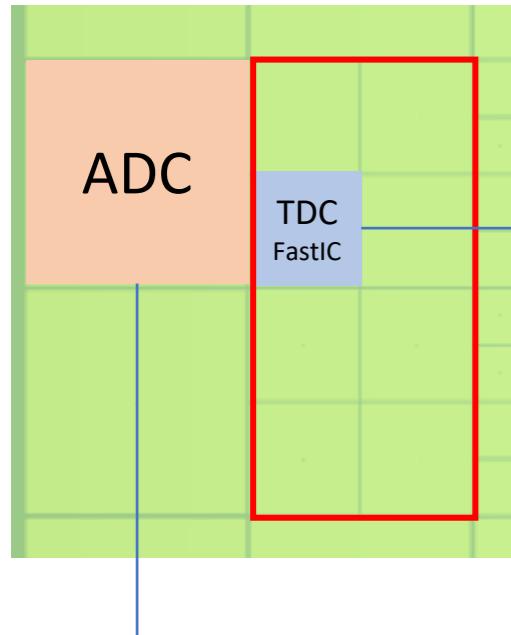
- 8 CH ASIC
- Technology 65 nm CMOS
- $\sim 6 \text{ mW/ch}$
- Number of channels: 8 SE / 4 DIFF
- Connection Type Configurable SE (Pos/Neg polarity) DIFF, Sum of 4 (Pos/Neg polarity)
- Electronics Time Jitter $\sim 25 \text{ ps rms}$
- Energy Resolution Linear ($\sim 2.5\%$ Linearity error)



- 8 channels connected to $\frac{1}{2}''$ pads
- Timing resolution at different positions of laser spot $\approx 115 \text{ ps}$ – no time-walk correction

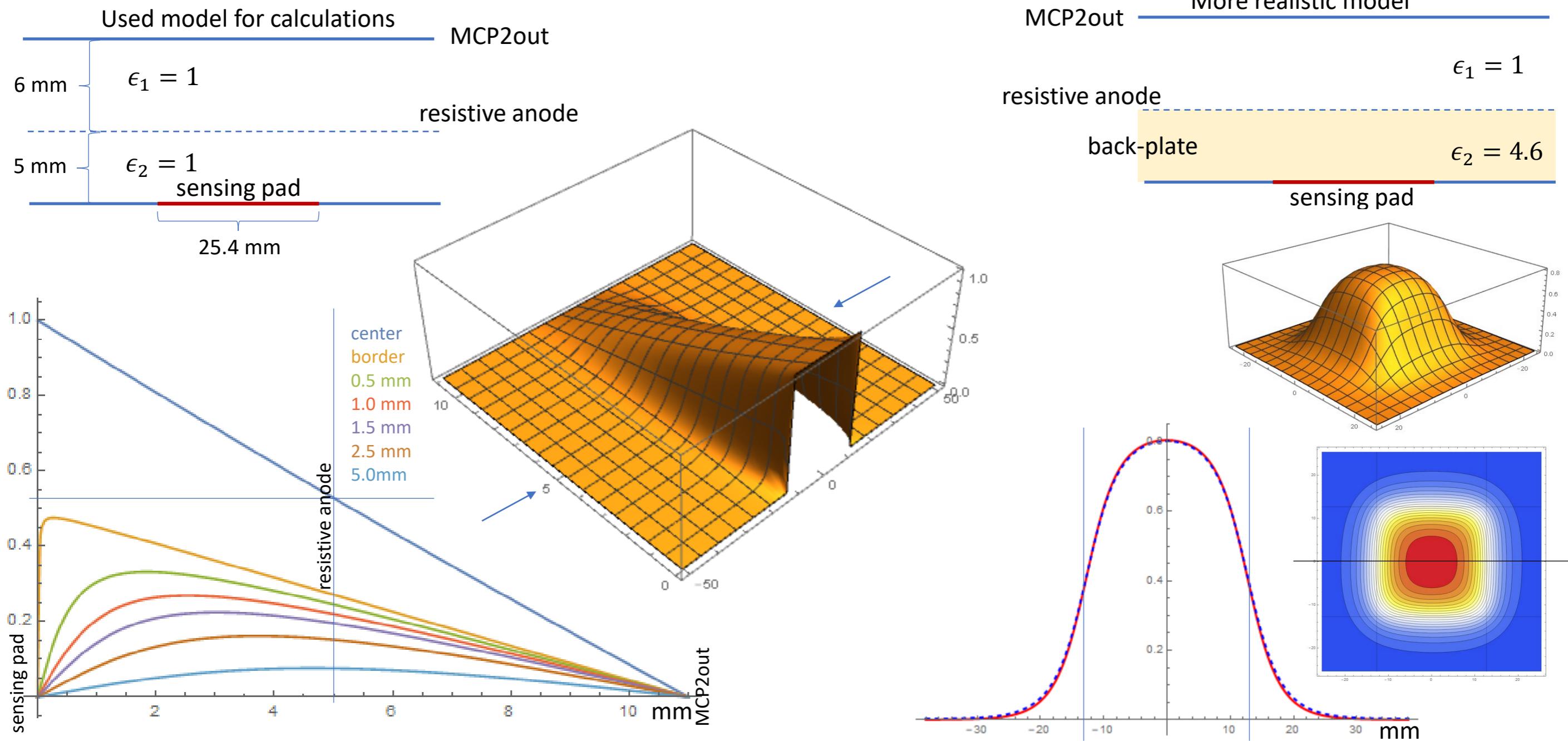


- Signal too short for TOT detection (may be possible with adjusted FastIC parameters?)
- Charge measured by charge sharing on adjacent pad
- Timing resolution corrected for time-walk by using ADC signal from neighbouring pad $\approx 70 \text{ ps}$



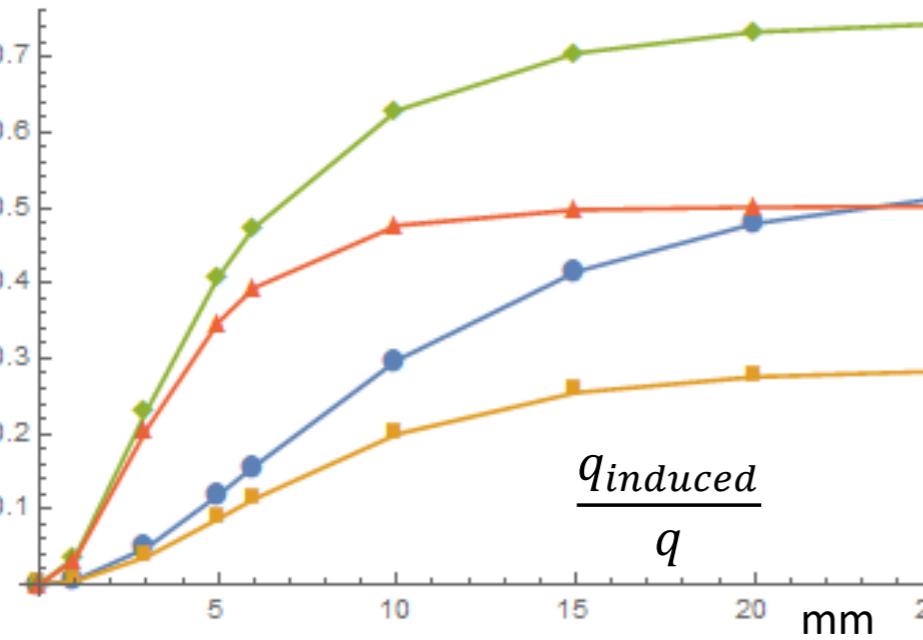
BACKUP SLIDES

LAPPD - induced charge calculations

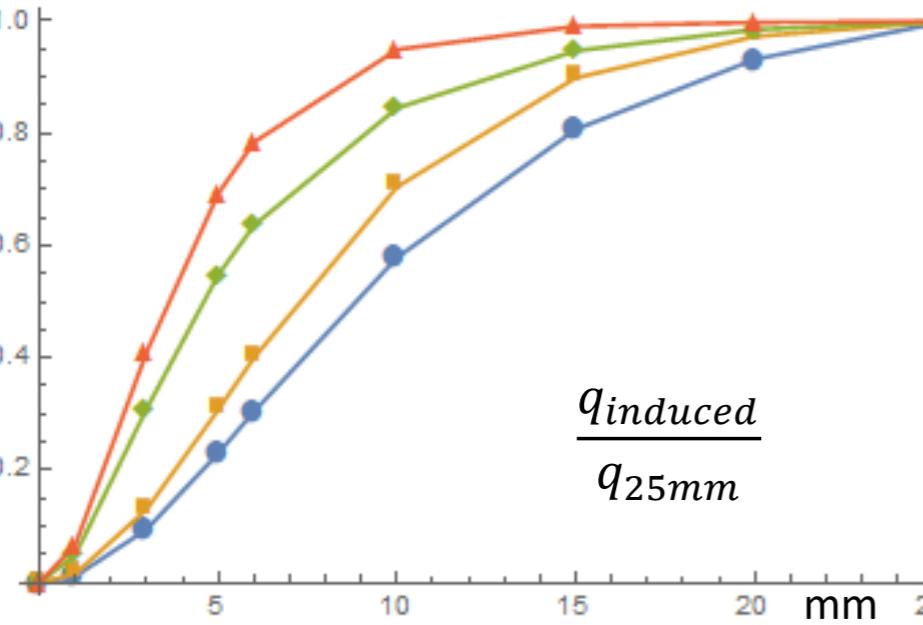


LAPPD - induced charge estimates

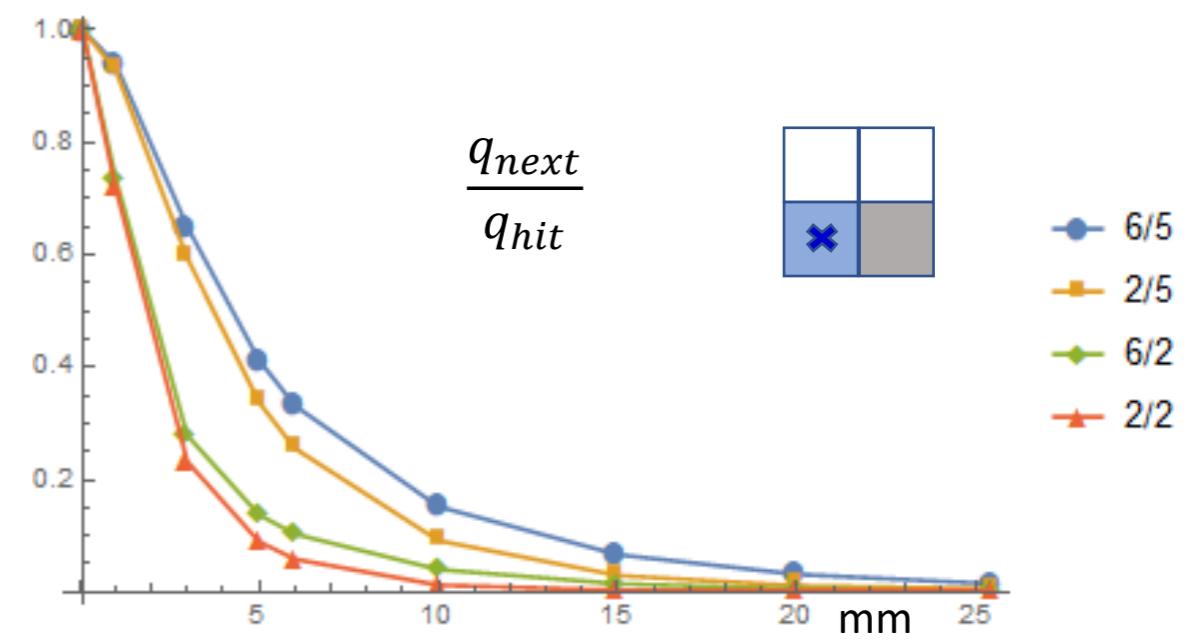
Collected charge by pads of different size and for different (MCP2out-A)/(A-pad) distances. ϵ not included.



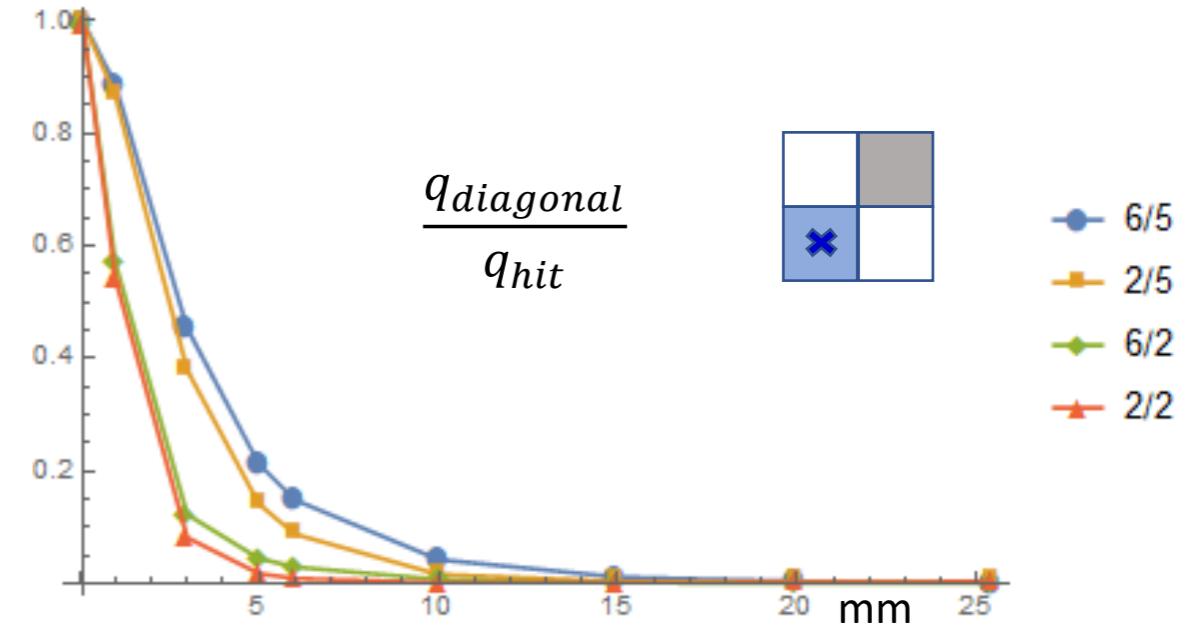
$$\frac{q_{induced}}{q}$$



$$\frac{q_{induced}}{q_{25mm}}$$



$$\frac{q_{next}}{q_{hit}}$$

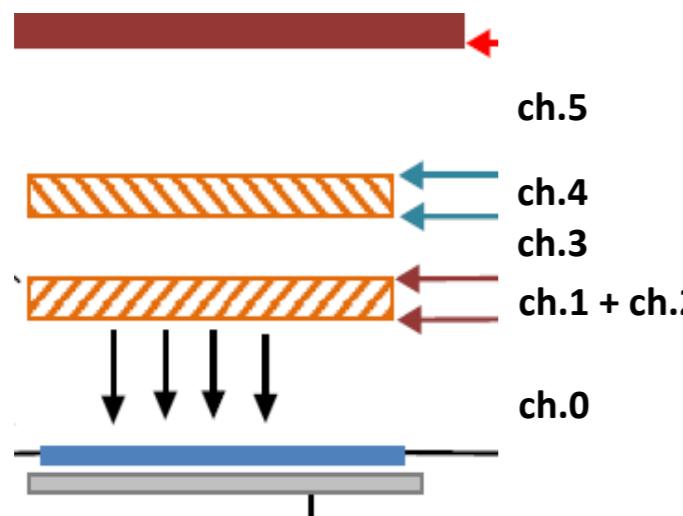


$$\frac{q_{diagonal}}{q_{hit}}$$

LAPPD - HV supply

CAEN HiVolta (DT1415ET), 8 Ch Reversible 1 kV/1 mA Desktop HV Power Supply – floating channels

- 1 kV/1 mA and 0.6 W(!) per channel
- ch.0 MCP2out – AN
- ch.1+ch.2 MCP2in – MCP2out (2 ch. due to power limit per channel)
- ch.3 MCP1out – MCP2in
- ch.4 MCP1in – MCP1out
- ch.5 PC – MCP1in

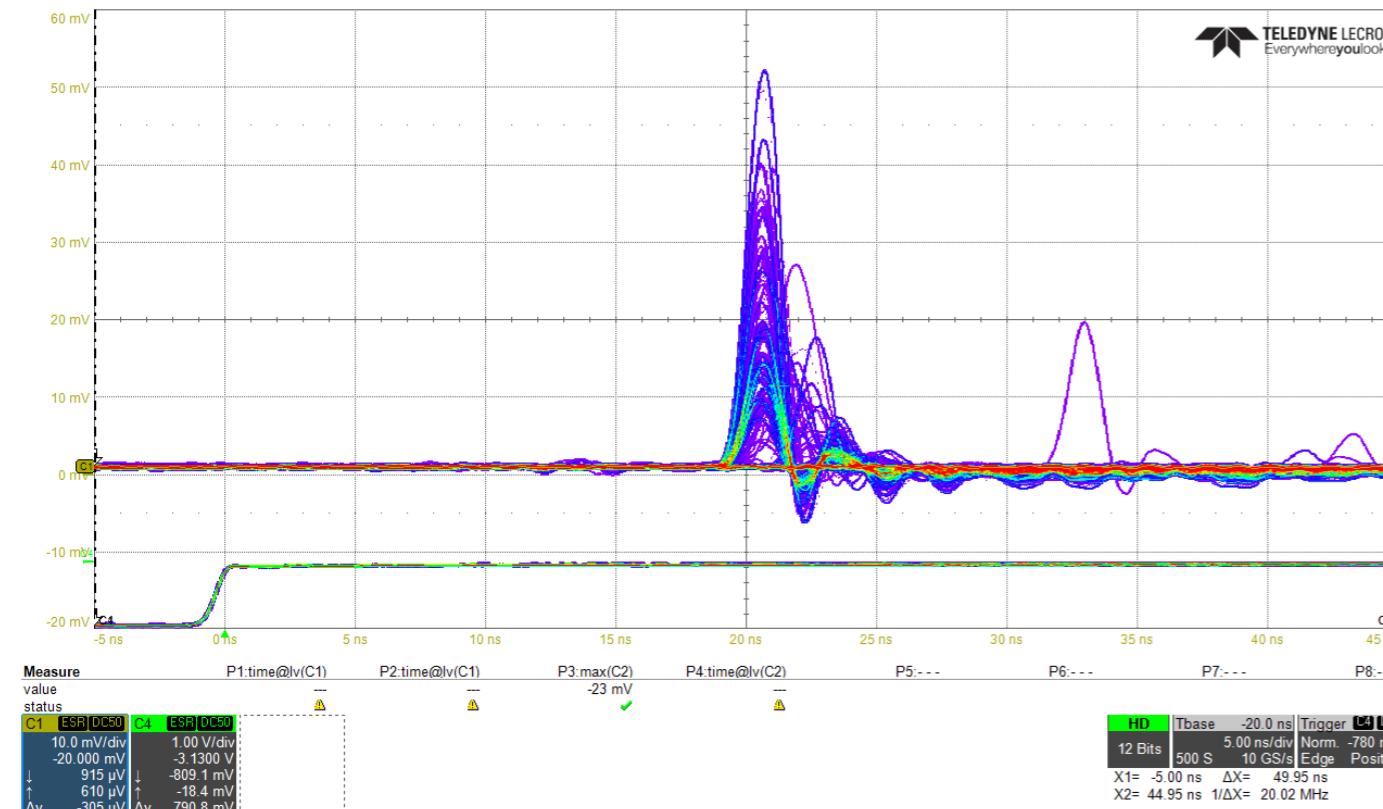


ROP voltages A-PC: 500/825(400+425)/200/825/100 V

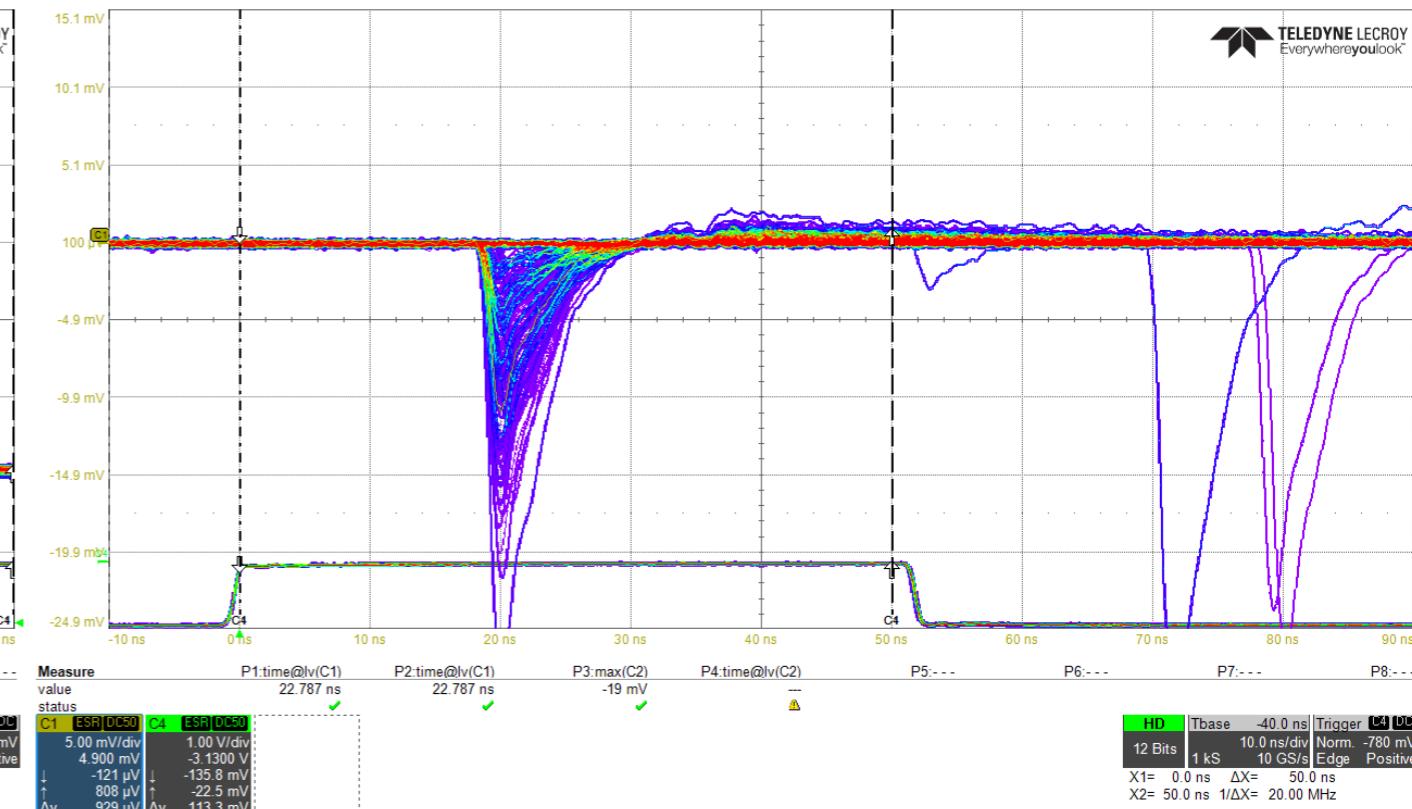
Custom	VSet	VMon	IMon	ISet	Pw	Status	SWVmax
00.000	500.00	500.06	3.8730	50.00	On		500
00.001	400.00	400.16	791.5960	900.00	On		400
00.002	425.00	425.30	791.7310	900.00	On		450
00.003	200.00	200.22	15.7010	50.00	On		200
00.004	825.00	825.46	345.5840	450.00	On		850
00.005	100.00	100.20	0.0680	5.00	On		150

LAPPD - raw signals

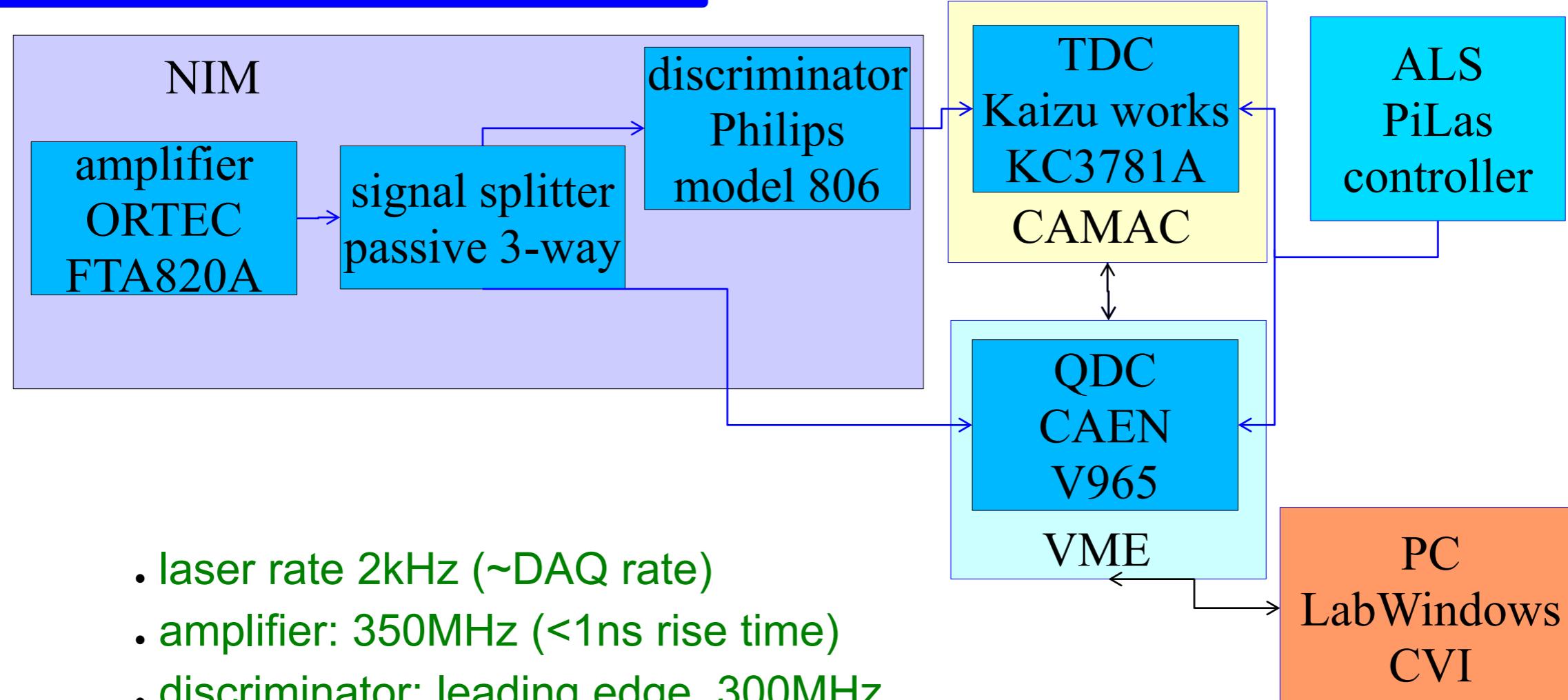
- transformed signal



- direct signal



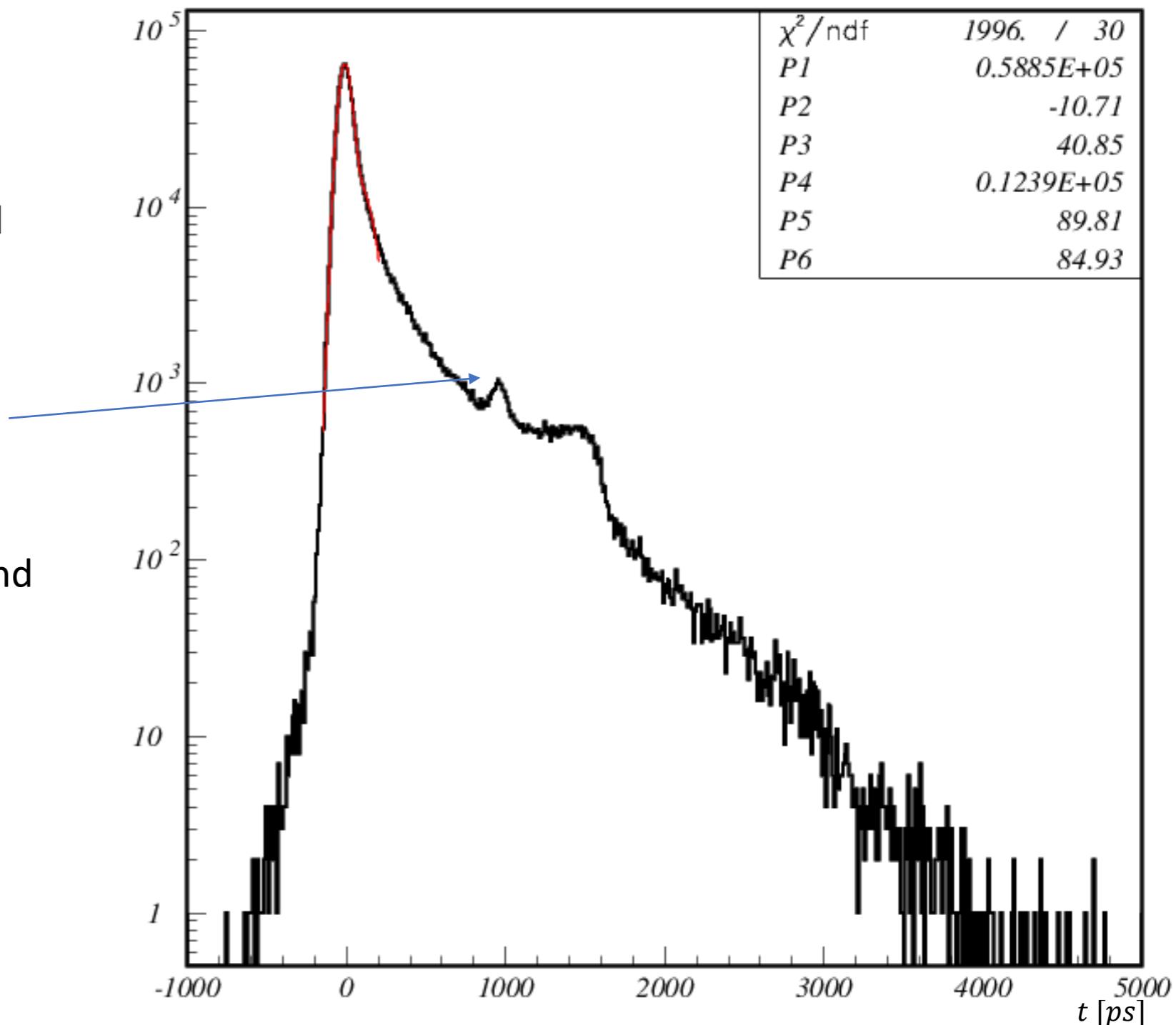
Modular readout system for tests



- laser rate 2kHz (~DAQ rate)
- amplifier: 350MHz (<1ns rise time)
- discriminator: leading edge, 300MHz
- TDC: 25ps LSB($\sigma \sim 11\text{ps}$)
- QDC: dual range 800pC, 200pC

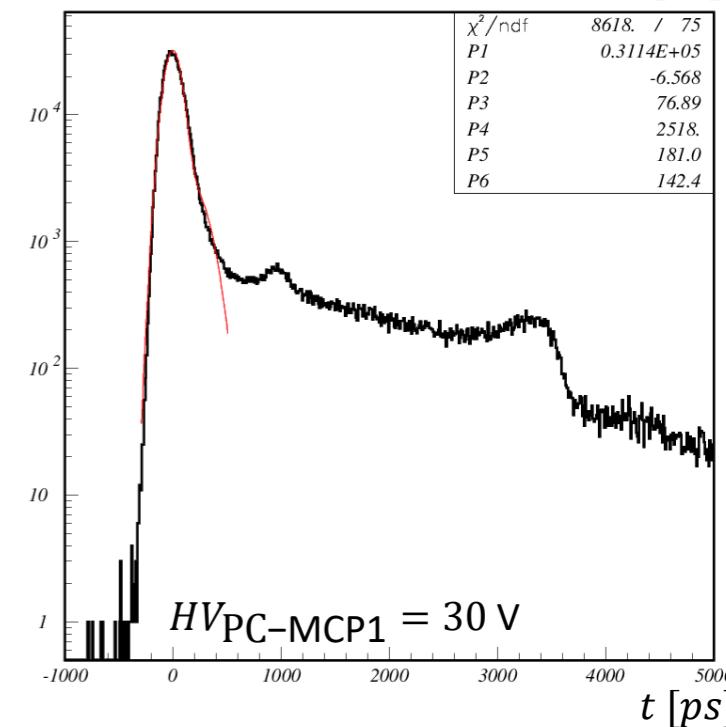
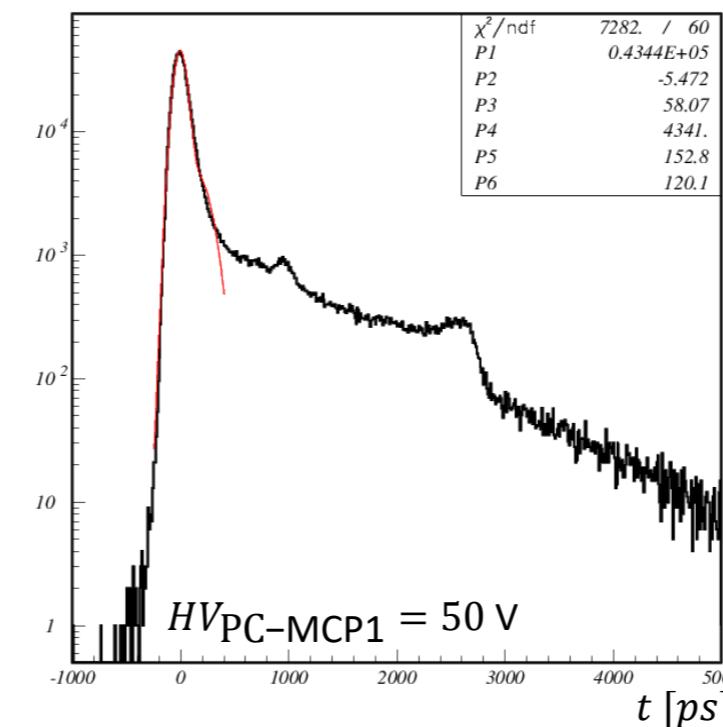
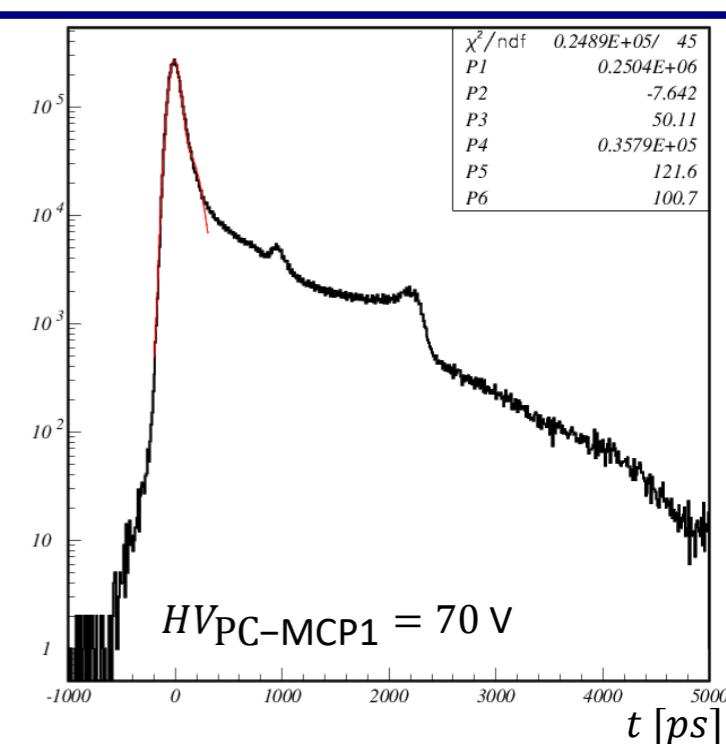
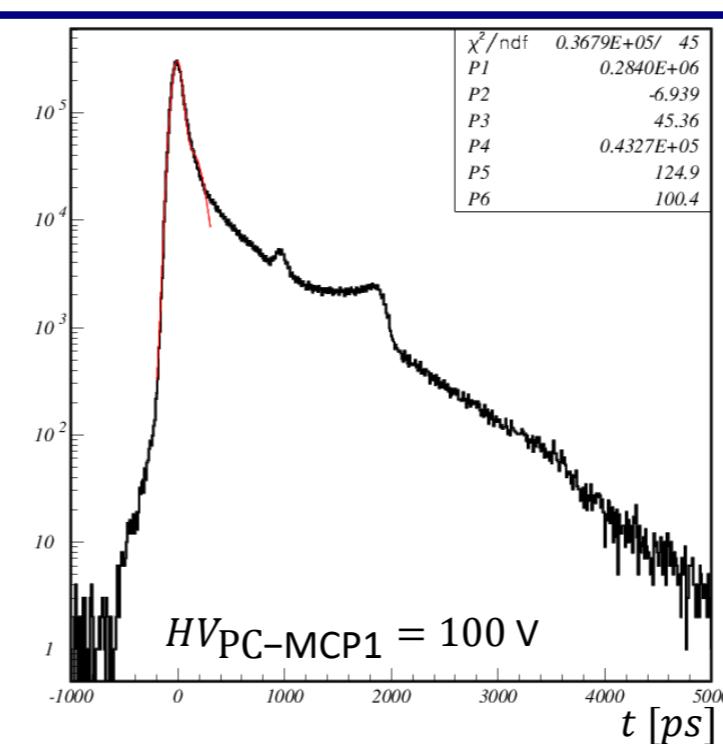
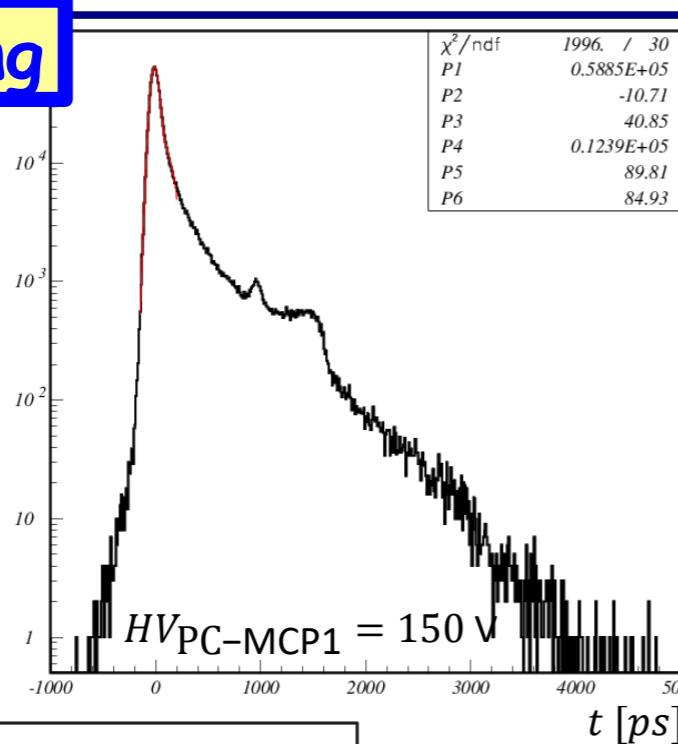
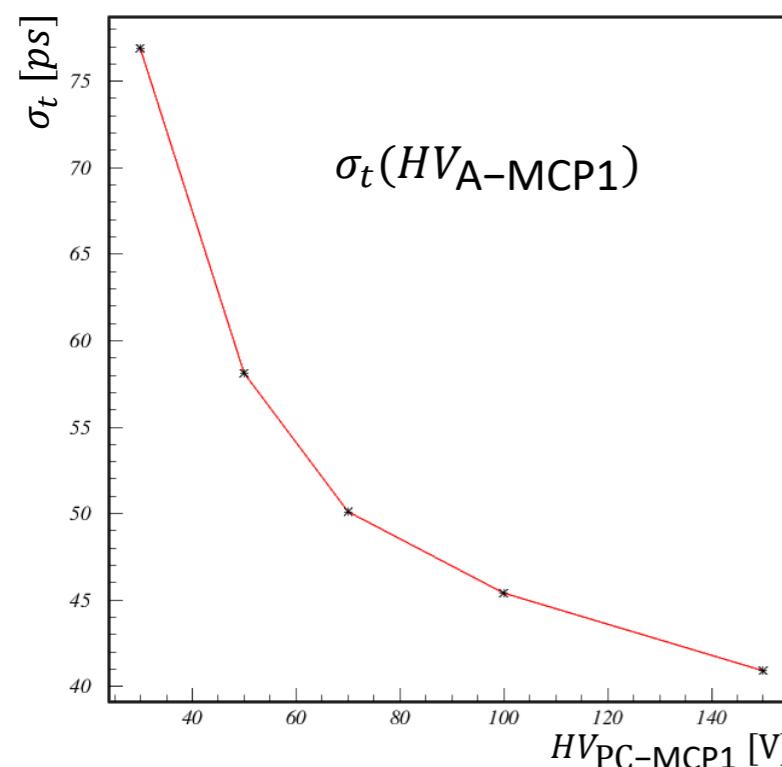
LAPPD - timing distribution

- measured timing distribution typical for MCP-PMT
- main prompt peak with some inelastic and elastic backscattering contribution
- additional small peak at about 1 ns delay probably due to some reflection (light?), delay not affected by PC-MCP1 voltage
- plot is for the PC-MCP1 voltage of 150 V and ROP for others



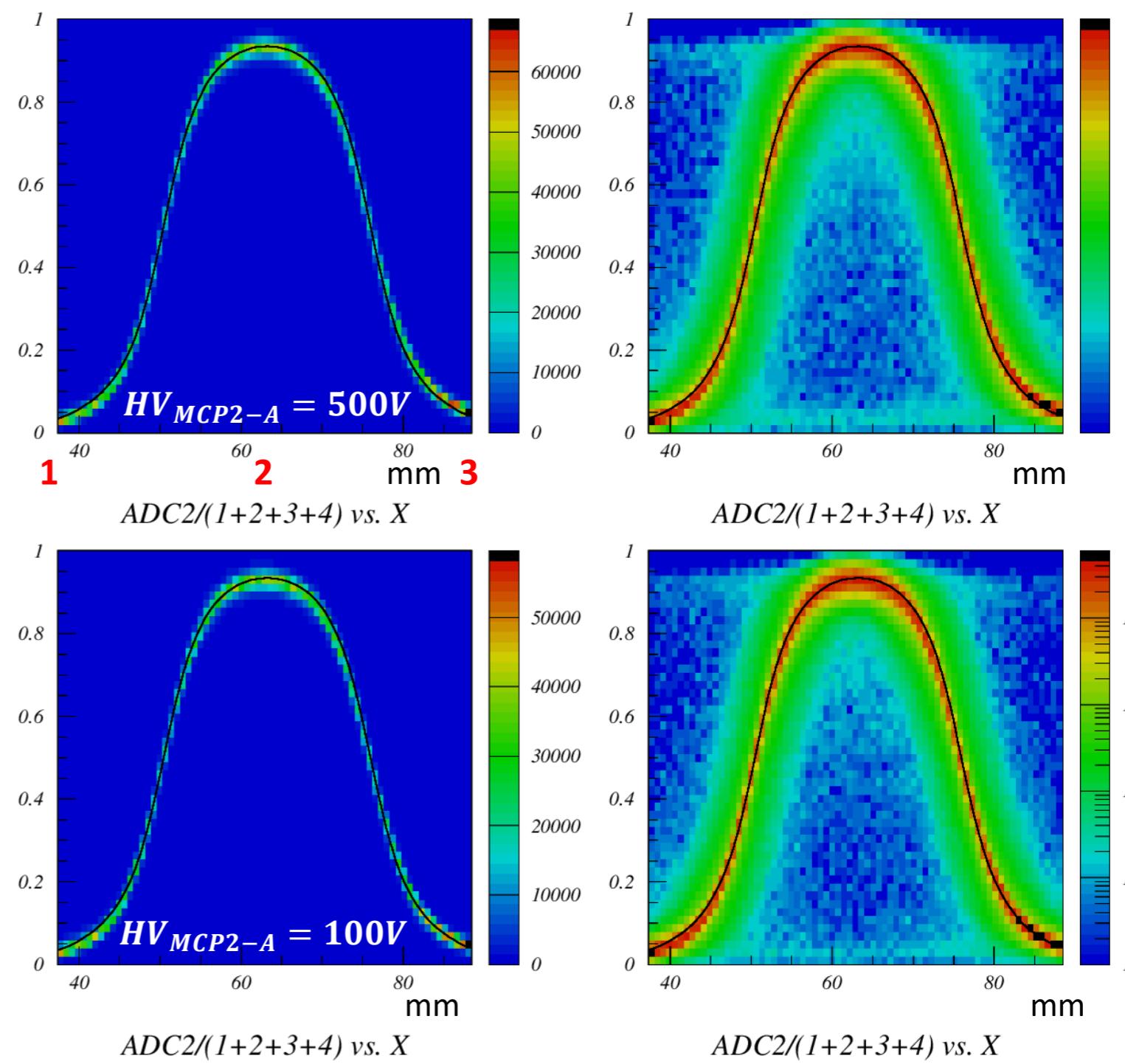
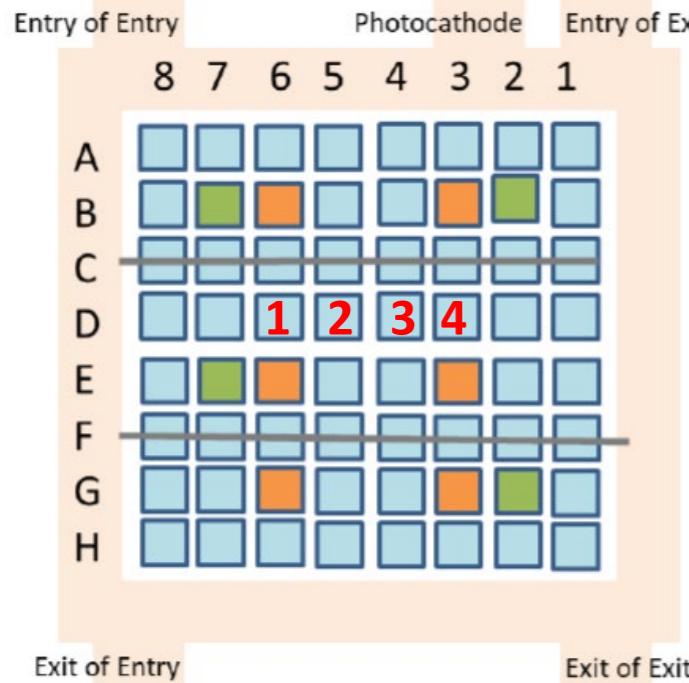
LAPPD - timing

- corrected TDCs for several PC-MCP1 voltages
- time resolution vs PC-MCP1 voltage



LAPPD - induced charge fraction

- fraction of the signal on ch. 2 vs laser spot x position: $f(x) = \frac{q_2}{\sum_i q_i}$
- green band (log scale) indicates the range of a backscattered photoelectrons – twice the PC-MC1 distance (on each side)
- ROP for upper plots and 100 V between MCP2 and A for lower ones
- Signal spread not mainly from electron spread but induced charge spread on coupled electrode



LAPPD (capacitive coupling) – BURLE PLANACON (internal anodes) signal spread comparison – same pad size, same range

